





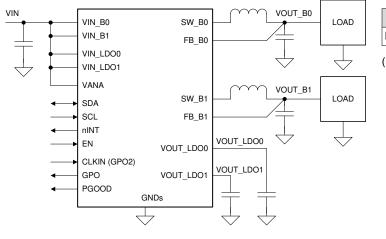


LP87332D-Q1 ZHCSGT8A - SEPTEMBER 2017 - REVISED JUNE 2021

LP87332D-Q1 双路高电流降压转换器和双路线性稳压器

1 特性

- 具有符合 AEC-Q100 标准的下列特性:
 - 器件温度等级 1:-40°C 至 +125°C 环境工作温 度范围
- 输入电压: 2.8V 至 5.5V
- 两个高效降压直流/直流转换器:
 - 输出电压: 0.7V 至 3.36V
 - 最大输出电流为 3A
 - 可编程输出电压压摆率范围: 0.5mV/µs 至 10mV/µs
 - 2MHz 开关频率
 - 用于降低 EMI 的扩频模式和相位交错
- 两个线性稳压器:
 - 输入电压: 2.5V 至 5.5V - 输出电压: 0.8V 至 3.3V — 最大输出电流为 300mA
- 可配置通用输出信号(GPO、GPO2)
- 具有可编程屏蔽的中断功能
- 可编程电源正常信号 (PGOOD)
- 输出短路和过载保护
- 过热警告和保护
- 过压保护 (OVP) 和欠压锁定 (UVLO)
- 具有可湿性侧面的 28 引脚、5mm×5mm VQFN 封



简化版原理图

2 应用

- 汽车音响主机和仪表组
- 汽车摄像头模块
- 环视系统 ECU
- 雷达系统 ECU
- 汽车显示屏

3 说明

LP87332D-Q1 旨在满足汽车摄像头和雷达应用中新型 处理器和平台的电源管理要求。该器件具有两个降压直 流/直流转换器、两个线性稳压器以及两个通用数字输 出信号。该器件由 I²C 兼容串行接口和使能信号进行控

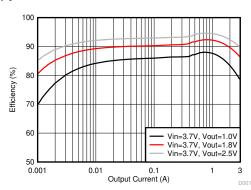
自动 PWM/PFM(AUTO 模式)运行,可在较宽输出 电流范围内提供高效率。LP87332D-Q1 支持远程电压 感应,可补偿稳压器输出与负载点 (POL) 之间的 IR 压 降,从而提高输出电压的精度。此外,可以强制开关时 钟进入 PWM 模式以及将其与外部时钟同步,从而更大 限度地降低干扰。

LP87332D-Q1 器件还支持可编程启动、关断延迟与时 序控制(包括与使能信号同步的 GPO 信号)。在启动 和电压变化期间,器件会对输出转换率进行控制,从而 更大限度地减小输出电压过冲和浪涌电流。

器件信息(1)

器件型号	封装	封装尺寸(标称值)
LP87332D-Q1	VQFN (28)	5.00mm × 5.00mm

(1) 如需了解所有可用封装,请参阅数据表末尾的可订购产品附 录。



直流/直流效率与输出电流间的关系

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English Data Sheet: SNVSAT1



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4 Revision History 注:以前版本的页码可能与当前版本的页码不同

С	hanges from Revision * (September 2017) to Revision A (June 2021)	Page
•	更新了整个文档中的表、图和交叉参考的编号格式	1
•	Updated the LDO Output Capacitor Selection section	<mark>61</mark>



5 Pin Configuration and Functions

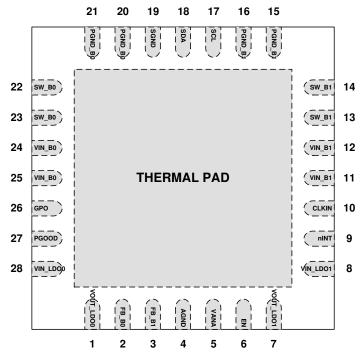


图 5-1. RHD Package 28-Pin VQFN With Thermal Pad Top View

表 5-1. Pin Functions

	PIN	TYPE ⁽¹⁾	DESCRIPTION
NUMBER	NAME	ITPE	DESCRIPTION
1	VOUT_LDO0	P/O	LDO0 output. If the LDO0 is not used, leave the pin floating.
2	FB_B0	Α	Output voltage feedback (positive) for Buck 0.
3	FB_B1	Α	Output voltage feedback (positive) for Buck 1
4	AGND	G	Ground.
5	VANA	P/I	Supply voltage for analog and digital blocks. Must be connected to same node with VIN_Bx.
6	EN	D/I	Programmable enable signal for regulators and GPOs. If the pin is not used, leave the pin floating.
7	VOUT_LDO1	P/O	LDO1 output. If LDO1 is not used, leave the pin floating.
8	VIN_LDO1	P/I	Power input for LDO1. If LDO1 is not used, connect the pin to VANA.
9	nINT	D/O	Open-drain interrupt output. Active LOW. If the pin is not used, connect the pin to ground.
10	CLKIN	D/I/O	External clock input. Alternative function is general-purpose digital output (GPO2). If the pin is not used, leave the pin floating.
11, 12	VIN_B1	P/I	Input for Buck 1. The separate power pins VIN_Bx are not connected together internally - VIN_Bx pins must be connected together in the application and be locally bypassed.
13, 14	SW_B1	P/O	Buck 1 switch node. If the Buck 1 is not used, leave the pin floating.
15, 16	PGND_B1	P/G	Power ground for Buck 1.
17	SCL	D/I	Serial interface clock input for I ² C access. Connect a pullup resistor. If the I ² C interface is not used, connect the pin to Ground.
18	SDA	D/I/O	Serial interface data input and output for I ² C access. Connect a pullup resistor. If the I ² C interface is not used, connect the pin to Ground.
19	SGND	G	Ground.
20, 21	PGND_B0	P/G	Power ground for Buck 0.
22, 23	SW_B0	P/O	Buck 0 switch node. If the Buck 0 is not used, leave the pin floating.



表 5-1. Pin Functions (continued)

	PIN		DESCRIPTION	
NUMBER	NAME	TYPE ⁽¹⁾	DESCRIPTION	
24, 25	VIN_B0	P/I	Input for Buck 0. The separate power pins VIN_Bx are not connected together internally - VIN_Bx pins must be connected together in the application and be locally bypassed.	
26	GPO	D/O	General-purpose digital output. If the pin is not used, leave the pin floating.	
27	PGOOD	D/O	Power-good indication signal. If the pin is not used, leave the pin floating.	
28	VIN_LDO0	P/I	Power input for LDO0. If the LDO0 is not used, connect the pin to VANA.	
Thermal Pad	_	_	Connect to PCB ground plane using multiple vias for good thermal performance.	

(1) A: Analog Pin, D: Digital Pin, G: Ground Pin, P: Power Pin, I: Input Pin, and O: Output Pin.



6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)(1) (2)

		MIN	MAX	UNIT
VIN_Bx, VANA	Voltage on power connections (must use the same input supply)	-0.3	6	V
VIN_LDOx	Voltage on power connections	-0.3	6	V
SW_Bx	Voltage on buck switch nodes	-0.3	(VIN_Bx + 0.3 V) with 6-V maximum	V
FB_Bx	Voltage on buck voltage sense nodes	-0.3	(VANA + 0.3 V) with 6-V maximum	V
VOUT_LDOx	Voltage on LDO output	-0.3	(VIN_LDOx + 0.3 V) with 6-V maximum	V
SDA, SCL, nINT, EN	Voltage on logic pins (input or output pins)	-0.3	6	V
PGOOD, GPO, CLKIN (GPO2)	Voltage on logic pins (input or output pins)	-0.3	(VANA + 0.3 V) with 6-V maximum	V
T _{J-MAX}	Junction temperature	-40	150	
T _{stg}	Storage temperature	-65	150	°C
Maximum lead temperat	ture (soldering, 10 seconds)		260	

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under # 6.3. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

					VALUE	UNIT
			Human-body model (HBM), per AEC Q100-	-002 ⁽¹⁾	±2000	
\ _V ,	ESD)	Electrostatic discharge	Channel device medal (CDM) non AEC	All pins	±500	V
	(230)		Charged-device model (CDM), per AEC Q100-011	Corner pins (1, 7, 8, 14, 15, 21, 22, 28)	±750	•

⁽¹⁾ AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
INPUT VOLTAGE				
VIN_Bx, VANA	Voltage on power connections (must use the same input supply)	2.8	5.5	V
VIN_LDOx	Voltage on LDO inputs	2.5	5.5	V
EN, nINT	Voltage on logic pins (input or output pins)	0	5.5	V
CLKIN	Voltage on logic pins (input pin)	0	VANA with 5.5-V maximum	V
PGOOD, GPO, GPO2	Voltage on logic pins (output pins)	0	VANA	V
CCI CDA	Voltage on I2C interface, Standard (100 kHz), Fast (400 kHz), Fast+ (1 MHz), and High-Speed (3.4 MHz) Modes	0	maximum 0 VANA 0 1.95	V
SCL, SDA	Voltage on I2C interface, Standard (100 kHz), Fast (400 kHz), and Fast+ (1 MHz) Modes	0	VANA with 3.6-V maximum	V
TEMPERATURE				
T _J	Junction temperature	-40	140	°C
T _A	Ambient temperature	-40	125	°C

⁽²⁾ All voltage values are with respect to network ground.



6.4 Thermal Information

		LP87332D-Q1	
	THERMAL METRIC ⁽¹⁾	RHD (VQFN)	UNIT
		28 PINS	
R _{0JA}	Junction-to-ambient thermal resistance	36.7	°C/W
R _{0JCtop}	Junction-to-case (top) thermal resistance	26.6	°C/W
R _{0JB}	Junction-to-board thermal resistance	8.9	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	8.8	°C/W
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	2.2	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

6.5 Electrical Characteristics

Limits apply over the junction temperature range $-40^{\circ}\text{C} \le T_{J} \le +140^{\circ}\text{C}$, specified V_{VANA} , V_{VIN_Bx} , V_{VIN_LDOx} , V_{VOUT_Bx} , V_{VOUT_LDOx} and I_{OUT} range, unless otherwise noted. Typical values are at $T_{J} = 25^{\circ}\text{C}$, $V_{VANA} = V_{VIN_Bx} = V_{VIN_LDOx} = 3.7 \text{ V}$, and $V_{OUT} = 1 \text{ V}$, unless otherwise noted⁽¹⁾ (2).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
EXTERNAL (COMPONENTS					
C _{IN_BUCK}	Input filtering capacitance for buck regulators	Effective capacitance, connected from VIN_Bx to PGND_Bx	1.9	10		μF
C _{OUT_BUCK}	Output filtering capacitance for buck regulators	Effective capacitance	10	22	500	μF
C _{POL_BUCK}	Point-of-load (POL) capacitance for buck regulators	Optional POL capacitance		22		μF
C _{OUT-} TOTAL_BUCK	Buck output capacitance, total (local and POL)	Total output capacitance			500	μF
C _{IN_LDO}	Input filtering capacitance for LDO regulators	Effective capacitance, connected from VIN_LDOx to AGND. C _{IN_LDO} must be at least two times larger than C _{OUT_LDO}	0.6	2.2		μF
C _{OUT_LDO}	Output filtering capacitance for LDO regulators	Effective capacitance	0.4	1	2.7	μF
ESR _C	Input and output capacitor ESR	[1-10] MHz		2	10	mΩ
L	Inductor	Inductance of the inductor	-30%	0.47	30%	μΗ
DCRL	Inductor DCR			25		mΩ
BUCK REGU	ILATORS					
V _(VIN_Bx) , V _(VANA)	Input voltage range	VIN_Bx and VANA pins must be connected to the same supply line	2.8	3.7	5.5	V
		Programmable voltage range	0.7	1	3.36	V
V	Output voltage	Step size, 0.7 V ≤ V _{OUT} < 0.73 V		10		
V_{OUT_Bx}	Output voltage	Step size, 0.73 V ≤ V _{OUT} < 1.4 V		5		mV
		Step size, 1.4 V ≤ V _{OUT} ≤ 3.36 V		20		
I _{OUT_Bx}	Output current	Output current			3(3)	Α
	Input and Output voltage difference	Minimum voltage between V _(VIN_Bx) and V _{OUT} to fulfill the electrical characteristics	0.8			V

Product Folder Links: LP87332D-Q1

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Limits apply over the junction temperature range $-40^{\circ}\text{C} \le T_{J} \le +140^{\circ}\text{C}$, specified V_{VANA} , V_{VIN_Bx} , V_{VIN_LDOx} , V_{VOUT_Bx} , V_{VOUT_LDOx} and I_{OUT} range, unless otherwise noted. Typical values are at $T_{J} = 25^{\circ}\text{C}$, $V_{VANA} = V_{VIN_Bx} = V_{VIN_LDOx} = 3.7 \text{ V}$, and $V_{OUT} = 1 \text{ V}$, unless otherwise noted⁽¹⁾ (2).

P	ARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		Force PWM mode, V _{OUT} < 1 V	-20		20	mV
	DC output voltage accuracy, includes voltage reference, DC load and line regulations, process and temperature	Force PWM mode, V _{OUT} ≥ 1 V	-2%		2%	
$V_{OUT_Bx_DC}$		PFM mode, V _{OUT} < 1 V, the average output voltage level is increased by max. 20 mV	-20		40	mV
		PFM mode, V _{OUT} ≥ 1 V, the average output voltage level is increased by max. 20 mV	-2%		2% + 20 mV	
	Dinnle veltage	PWM mode		10		m\/
	Ripple voltage	PFM mode, I _{OUT} = 10 mA		25		mV_{p-p}
DC _{LNR}	DC line regulation	I _{OUT} = 1 A		±0.05		%/V
DC_{LDR}	DC load regulation in PWM mode	$V_{OUT_Bx} = 1 \text{ V}, I_{OUT} \text{ from 0 to } I_{OUT(max)}$		0.3%		
T _{LDSR}	Transient load step response	I_{OUT} = 0.1 A to 2 A, T_R = T_F = 400 ns, PWM mode		±55		mV
T _{LNSR}	Transient line response	$V_{(VIN_Bx)}$ stepping 3 V \leftrightarrow 3.5 V, T_R = T_F = 10 μ s, I_{OUT} = $I_{OUT(max)}$		±10		mV
		Programmable range	1.5		4	Α
l 5.105	Forward current limit per phase (peak for every	Step size		0.5		
I _{LIM} FWD	switching cycle)	Accuracy, V _(VIN_Bx) ≥ 3 V, I _{LIM} = 4 A	-5%	7.5%	20%	
		Accuracy, 2.8 V ≤ V _(VIN_Bx) < 3 V, I _{LIM} = 4 A	-20%	7.5%	20%	
I _{LIM NEG}	Negative current limit per phase		1.6	2.0	3.0	Α
R _{DS(ON)} HS FET	On-resistance, high-side FET	Each phase, between VIN_Bx and SW_Bx pins (I = 1 A)		50	110	mΩ
R _{DS(ON)} LS FET	On-resistance, low-side FET	Each phase, between SW_Bx and PGND_Bx pins (I = 1 A)		45	90	mΩ
$f_{\sf SW}$	Switching frequency	PWM mode	1.8	2	2.2	MHz
	Start-up time (soft start)	From ENx to V _{OUT_Bx} = 0.35 V (slew-rate control begins)		120		μs
		SLEW_RATEx[2:0] = 010, C _{OUT-TOTAL_BUCK} < 80 μF		10		
		SLEW_RATEx[2:0] = 011, C _{OUT-TOTAL_BUCK} < 130 µF		7.5		
	Output voltage slew-	SLEW_RATEx[2:0] = 100, C _{OUT-TOTAL_BUCK} < 250 µF	-15% —	3.8	15%	mV/us
	rate ⁽⁴⁾	SLEW_RATEx[2:0] = 101, C _{OUT-TOTAL_BUCK} < 500 μF	-1070	1.9	1370	πνημο
		SLEW_RATEx[2:0] = 110, C _{OUT-TOTAL_BUCK} < 500 μF		0.94		
		SLEW_RATEx[2:0] = 111, C _{OUT-TOTAL_BUCK} < 500 μF		0.47		
I _{PFM-PWM}	PFM-to-PWM - current threshold ⁽⁵⁾			550		mA
I _{PWM-PFM}	PWM-to-PFM - current threshold ⁽⁵⁾			290		mA
R _{DIS_Bx}	Output pulldown resistance	Regulator disabled	150	250	350	Ω



Limits apply over the junction temperature range $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le +140^{\circ}\text{C}$, specified V_{VANA} , $\text{V}_{\text{VIN_Bx}}$, $\text{V}_{\text{VIN_LDOx}}$, $\text{V}_{\text{VOUT_Bx}}$, $\text{V}_{\text{VOUT_LDOx}}$ and I_{OUT} range, unless otherwise noted. Typical values are at $\text{T}_{\text{J}} = 25^{\circ}\text{C}$, $\text{V}_{\text{VANA}} = \text{V}_{\text{VIN_Bx}} = \text{V}_{\text{VIN_LDOx}} = 3.7 \text{ V}$, and $\text{V}_{\text{OUT}} = 1 \text{ V}$, unless otherwise noted⁽¹⁾ (2).

l	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		V _(VIN_Bx) and V _(VANA) fixed 3.7 V				
	Output voltage monitoring for PGOOD	Overvoltage threshold (compared to DC output voltage level, V _{VOUT_Bx_DC})	39	50	64	mV
	pin and for power-good Interrupt	Undervoltage threshold (compared to DC output voltage level, V _{VOUT_Bx_DC})	-53	-40	-29	IIIV
		Deglitch time during operation and after voltage change	4		15	μs
	Gating time for PGOOD signal after regulator enable or voltage change	PGOOD_MODE = 0		800		μs
LDO REGULA	TORS				'	
V _{IN_LDOx}	Input voltage range for LDO power inputs	V _{IN_LDOx} can be higher or lower than V _(VANA)	2.5	3.7	5.5	V
Vollt i pov	Output voltage	Programmable voltage range	0.8		3.3	V
V_{OUT_LDOx}	Output voltage	Step size		0.1		V
I _{OUT_LDOx}	Output current				300	mA
	Dropout voltage	V _(VIN_LDOx) – V _(VOUT_LDOx) , I _{OUT} = I _{OUT(max)} , Programmed output voltage is higher than V _(VIN_LDOx)			200	mV
	DC output voltage	V _{OUT} < 1 V	-20		20	mV
V _{OUT_LDO_DC}	accuracy, includes voltage reference, DC load and line regulations, process, temperature	V _{OUT} ≥ 1 V	-2%		2%	
DC _{LNR}	DC line regulation	I _{OUT} = 1 mA		0.1		%/V
DC _{LDR}	DC load regulation	I _{OUT} = 1 mA to I _{OUT(max)}		0.8%		
T _{LDSR}	Transient load step response	I_{OUT} = 1 mA to 300 mA, T_R = T_F = 1 μ s		-50/+40		mV
T _{LNSR}	Transient line response	$V_{(VIN_LDOx)}$ stepping 3 V \leftrightarrow 3.5 V, $T_R = T_F = 10$ µs, $I_{OUT} = I_{OUT(max)}$		±7		mV
PSRR	Power supply ripple rejection	f = 10 kHz, $I_{OUT} = I_{OUT(max)}$		53		dB
	Noise	10 Hz < F < 100 kHz, I _{OUT} = I _{OUT(max)}		82		μV_{rms}
I _{SHORT(LDOx)}	LDO current limit	V _{OUT} = 0 V	400	500	600	mA
	Start-up time	From enable to valid output voltage		300		μs
	Slew rate during start-up			15		mV/μs
R _{DIS_LDOx}	Output pulldown resistance	Regulator disabled	150	250	350	Ω
		Overvoltage monitoring, voltage rising (compared to DC output voltage level, Vout_LDO_DC)	106%	108%	110%	
	Output voltage	Overvoltage monitoring, hysteresis	3%	3.5%	4%	
	monitoring for PGOOD pin and for power-good (Undervoltage monitoring, voltage falling (compared to DC output voltage level, Vout_LDO_DC)	90%	92%	94%	
		Undervoltage monitoring, hysteresis	3%	3.5%	4%	
		Deglitch time during operation and after voltage change	4		15	μs



Limits apply over the junction temperature range $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le +140^{\circ}\text{C}$, specified V_{VANA} , $V_{\text{VIN_Bx}}$, $V_{\text{VIN_LDOx}}$, $V_{\text{VOUT_Bx}}$, $V_{\text{VOUT_LDOx}}$ and I_{OUT} range, unless otherwise noted. Typical values are at $T_{\text{J}} = 25^{\circ}\text{C}$, $V_{\text{VANA}} = V_{\text{VIN_Bx}} = V_{\text{VIN_LDOx}} = 3.7 \text{ V}$, and $V_{\text{OUT}} = 1 \text{ V}$, unless otherwise noted⁽¹⁾ (2).

	1 V, unless otherwise note PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
	Gating time for PGOOD signal after regulator enable or voltage change	PGOOD_MODE = 0		800		μs	
EXTERNAL (CLOCK AND PLL						
		Nominal frequency	1		24	24 MHz	
f _{EXT_CLK}	External input clock ⁽⁶⁾	Nominal frequency step size		1		IVITIZ	
		Required accuracy from nominal frequency	-30%		10%		
	External clock detection	Delay for missing clock detection			1.8		
	External clock detection	Delay and debounce for clock detection			20	μs	
	Clock change delay (internal to external)	Delay from valid clock detection to use of external clock		600		μs	
	PLL output clock jitter	Cycle to cycle		300		ps, p-p	
PROTECTIO	N FUNCTIONS			-			
		Temperature rising, TDIE_WARN_LEVEL = 0	115	125	135		
	Thermal warning	Temperature rising, TDIE_WARN_LEVEL = 1	127	137	147	°C	
		Hysteresis		20			
	Thermal shutdown	Temperature rising	140	150	160	°C	
	Thermal shuldown	Hysteresis		20			
VANA _{OVP}	VANA overvoltage	Voltage rising	5.6	5.8	6.1	- V	
		Voltage falling	5.45	5.73	5.96		
		Hysteresis	40			mV	
\	VANA undervoltage lockout	Voltage rising	2.51	2.63	2.75	V	
VANA _{UVLO}		Voltage falling	2.5	2.6	2.7	· V	
	Buck short-circuit detection	Threshold	280	360	440	mV	
	LDO short-circuit detection	Threshold	190	300	450	mV	
LOAD CURR	ENT MEASUREMENT FOR	BUCK REGULATORS					
	Current measurement range	Maximum code			10.22	Α	
	Resolution	LSB		20		mA	
	Measurement accuracy	I _{OUT} > 1 A		<10%			
	Measurement time	PFM mode (automatically changing to PWM mode for the measurement)		45		μs	
		PWM mode	-	4			
CURRENT C	ONSUMPTION						
	Standby current consumption, regulators disabled			9		μA	
	Active current consumption, one buck regulator enabled in auto mode, internal RC oscillator, PGOOD monitoring enabled	I _{OUT_Bx} = 0 mA, not switching		58		μА	



Limits apply over the junction temperature range $-40^{\circ}\text{C} \le T_{J} \le +140^{\circ}\text{C}$, specified V_{VANA} , V_{VIN_Bx} , V_{VIN_LDOx} , V_{VOUT_Bx} , V_{VOUT_LDOx} and I_{OUT} range, unless otherwise noted. Typical values are at $T_{J} = 25^{\circ}\text{C}$, $V_{VANA} = V_{VIN_Bx} = V_{VIN_LDOx} = 3.7 \text{ V}$, and $V_{OUT} = 1 \text{ V}$, unless otherwise noted⁽¹⁾ (2).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Active current consumption, two buck regulators enabled in auto mode, internal RC oscillator, PGOOD monitoring enabled	I _{OUT_Bx} = 0 mA, not switching		100		μА
	Active current consumption during PWM operation, one buck regulator enabled	I _{OUT_Bx} = 0 mA		15		mA
	Active current consumption during PWM operation, two buck regulators enabled	I _{OUT_Bx} = 0 mA		30		mA
	LDO regulator enabled	Additional current consumption per LDO, I _{OUT_LDOx} = 0 mA		86		μΑ
	PLL and clock detector current consumption	f _{EXT_CLK} = 1 MHz, Additional current consumption when enabled		2		mA
DIGITAL IN	NPUT SIGNALS EN, SCL, SDA	, CLKIN				
V _{IL}	Input low level				0.4	V
V _{IH}	Input high level		1.2			v
V _{HYS}	Hysteresis of Schmitt Trigger inputs		10	80	200	mV
	EN/CLKIN pulldown resistance	EN_PD/CLKIN_PD = 1		500		kΩ
DIGITAL O	OUTPUT SIGNALS nINT, SDA					
V _{OL}	Output low level	nINT: I _{SOURCE} = 2 mA			0.4	V
▼OL	Output 1044 16461	SDA: I _{SOURCE} = 20 mA			0.4	V
R _P	External pullup resistor for nINT	To VIO Supply		10		kΩ
DIGITAL O	OUTPUT SIGNALS PGOOD, GF	PO, GPO2				
V _{OL}	Output low level	I _{SOURCE} = 2 mA			0.4	V
V _{OH}	Output high level, configured to push-pull	I _{SINK} = 2 mA	V _{VANA} - 0.4		V_{VANA}	V
V_{PU}	Supply voltage for external pullup resistor, configured to open-drain				V_{VANA}	V
R _{PU}	External pullup resistor, configured to open-drain			10		kΩ
ALL DIGIT	AL INPUTS				'	
I _{LEAK}	Input current	All logic inputs over pin voltage range	-1		1	μA

- (1) All voltage values are with respect to network ground.
- (2) Minimum (MIN) and Maximum (MAX) limits are specified by design, test, or statistical analysis. Typical (TYP) numbers are not verified, but do represent the most likely norm.
- (3) The maximum output current can be limited by the forward current limit I_{LIM FWD}. The power dissipation inside the die increases the junction temperature and limits the maximum current depending of the length of the current pulse, efficiency, board and ambient temperature.
- (4) The slew-rate can be limited by the current limit (forward or negative current limit), output capacitance and load current.
- (5) The final PFM-to-PWM and PWM-to-PFM switchover current varies slightly and is dependent on the output voltage, input voltage and the inductor current level.
- (6) The external clock frequency must be selected so that buck switching frequency is above 1.7 MHz.



6.6 I²C Serial Bus Timing Parameters

These specifications are ensured by design. Unless otherwise noted, V_{IN_Bx} = 3.7 V (see $^{(1)}$). See \boxtimes 6-1 for details about the I²C-Compatible Timing diagram.

			MIN	MAX	UNIT	
		Standard mode		100	kHz	
		Fast mode		400	KΠZ	
f _{SCL}	Serial clock frequency	Fast mode+		1		
		High-speed mode, C _b = 100 pF		3.4	MHz	
		High-speed mode, C _b = 400 pF		1.7		
		Standard mode	4.7			
		Fast mode	1.3			
LOW	SCL low time	Fast mode+	0.5		μs	
		High-speed mode, C _b = 100 pF	0.16			
		High-speed mode, C _b = 400 pF	0.32			
		Standard mode	4			
		Fast mode	0.6			
HIGH	SCL high time	Fast mode+	0.26		μs	
		High-speed mode, C _b = 100 pF	0.06			
		High-speed mode, C _b = 400 pF	0.12			
t _{SU;DAT}	Data setup time	Standard mode	250		- ns	
		Fast mode	100			
		Fast mode+	50			
		High-speed mode	10			
		Standard mode	10	3450	ns	
		Fast mode	10	900		
HD;DAT	Data hold time	Fast mode+	10			
		High-speed mode, C _b = 100 pF	10	70		
		High-speed mode, C _b = 400 pF	10	150		
		Standard mode	4.7			
	Setup time for a start	Fast mode	0.6			
t _{SU;STA}	or a repeated start condition	Fast mode+	0.26		μs	
		High-speed mode	0.16			
		Standard mode	4			
	Hold time for a start or a	Fast mode	0.6			
t _{HD;STA}	repeated start condition	Fast mode+	0.26		μs	
		High-speed mode	0.16			
		Standard mode	4.7			
t _{BUF}	Bus free time between a stop and start condition	Fast mode	1.3		μs	
	Stop and Start Condition	Fast mode +	0.5			
		Standard mode	4			
	Setup time for a stop	Fast mode	0.6			
t _{su;sto}	condition	Fast mode+	0.26		μs	
		High-speed mode	0.16			



6.6 I²C Serial Bus Timing Parameters (continued)

These specifications are ensured by design. Unless otherwise noted, V_{IN_Bx} = 3.7 V (see $^{(1)}$). See \boxtimes 6-1 for details about the I²C-Compatible Timing diagram.

			MIN	MAX	UNIT	
		Standard mode		1000		
		Fast mode	20	300		
t _{rDA}	Rise time of SDA signal	Fast mode+		120	ns	
		High-speed mode, C _b = 100 pF	10	80		
		High-speed mode, C _b = 400 pF	20	160		
		Standard mode		300		
		Fast mode	20 × (V _{DD} / 5.5 V)	300		
t _{fDA}	Fall time of SDA signal	Fast mode+	20 × (V _{DD} / 5.5 V)	120	ns	
		High-speed mode, C _b = 100 pF	10	80		
		High-speed mode, C _b = 400 pF	30	160		
		Standard mode		1000		
		Fast mode	20	300	ns	
t_{rCL}	Rise time of SCL signal	Fast mode+		120		
		High-speed mode, C _b = 100 pF	10	40		
		High-speed mode, C _b = 400 pF	20	80		
	Rise time of SCL signal	High-speed mode, C _b = 100 pF	10	80		
t _{rCL1}	after a repeated start condition and after an acknowledge bit	High-speed mode, C _b = 400 pF	20	160	ns	
		Standard mode		300		
		Fast mode	20 × (V _{DD} / 5.5 V)	300		
t _{fCL}	Fall time of a SCL signal	Fast mode+	20 × (V _{DD} / 5.5 V)	120	ns	
		High-speed mode, C _b = 10 – 100 pF	10	40		
		High-speed mode, C _b = 400 pF	20	80		
C _b	Capacitive load for each bus line (SCL and SDA)			400	pF	
	Pulse width of spike	Standard mode, fast mode, and fast mode+		50		
t _{SP}	suppressed (SCL and SDA spikes that are less then the indicated width are suppressed)	High-speed mode		10	ns	

⁽¹⁾ C_b refers to the capacitance of one bus line.



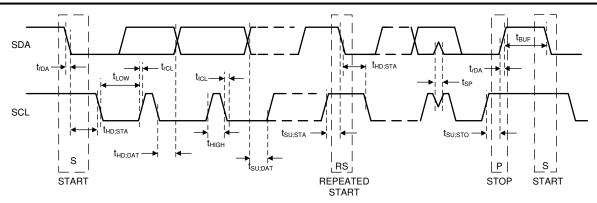
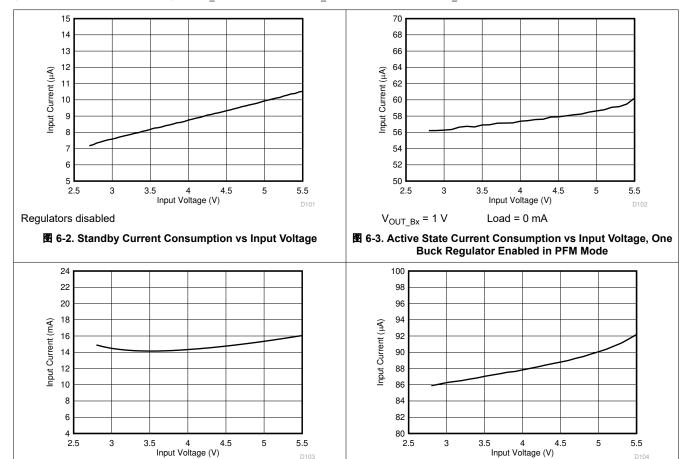


图 6-1. I²C-Compatible Timing



6.7 Typical Characteristics

Unless otherwise specified: $V_{(VIN_BX)} = V_{(VIN_LDOx)} = V_{(VANA)} = 3.7 \text{ V}, V_{OUT_BX} = 1 \text{ V}, V_{OUT_LDO} = 1 \text{ V}, T_A = 25^{\circ}\text{C}, L = 0.47 \ \mu\text{H}$ (TOKO DFE252012PD-R47M), $C_{OUT_BUCK} = 22 \ \mu\text{F}$, $C_{POL_BUCK} = 22 \ \mu\text{F}$, and $C_{OUT_LDO} = 1 \ \mu\text{F}$.



Load = 0 mA

 $V_{OUT_Bx} = 1 V$

图 6-5. Active State Current Consumption vs Input Voltage, One LDO Regulator Enabled

Load = 0 mA

 $V_{OUT_LDOx} = 1 V$



7 Detailed Description

7.1 Overview

The LP87332D-Q1 is a high-efficiency, high-performance flexible power supply device with two step-down DC/DC converter cores (Buck0 and Buck1) and two low-dropout (LDO) linear regulators (LDO0 and LDO1) for automotive applications. 表 7-1 lists the output characteristics of the regulators.

表 7-1. Supply Specification

CUDDLY	оитрит					
SUPPLY	V _{OUT} RANGE (V)	RESOLUTION (mV)	I _{MAX} MAXIMUM OUTPUT CURRENT (mA)			
Buck0	0.7 to 3.36	10 (0.7 V to 0.73 V) 5 (0.73 V to 1.4 V) 20 (1.4 V to 3.36 V)	3000			
Buck1	0.7 to 3.36	10 (0.7 V to 0.73 V) 5 (0.73 V to 1.4 V) 20 (1.4 V to 3.36 V)	3000			
LDO0	0.8 to 3.3	100	300			
LDO1	0.8 to 3.3	100	300			

The LP87332D-Q1 also supports switching clock synchronization to an external clock (CLKIN pin). The nominal frequency of the external clock can be from 1 MHz to 24 MHz with 1-MHz steps.

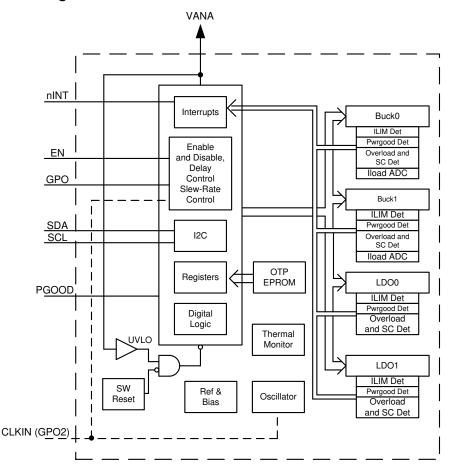
Additional features include:

- Soft-start
- Input voltage protection:
 - Undervoltage lockout
 - Overvoltage protection
- Output voltage monitoring and protection:
 - Overvoltage monitoring
 - Undervoltage monitoring
 - Overload protection
- · Thermal warning
- · Thermal shutdown

The LP87332D-Q1 has one dedicated general purpose digital output (GPO) signal. The CLKIN pin can be programmed as a second GPO signal (GPO2), if the external clock is not needed. The output type (open-drain or push-pull) is programmable for the GPOs.



7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 DC/DC Converters

7.3.1.1 Overview

The LP87332D-Q1 includes two step-down DC/DC converter cores. The cores are designed for flexibility; most of the functions are programmable, thus giving a possibility to optimize the regulator operation for each application. The buck regulators deliver 0.7-V to 3.36-V regulated voltage rails from a 2.8-V to 5.5-V supply voltage.

The LP87332D-Q1 has the following features:

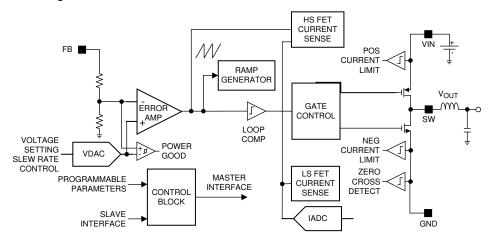
- · DVS support with programmable slew rate
- Automatic mode control based on the loading (PFM or PWM mode)
- Forced PWM mode option
- Optional external clock input to minimize crosstalk
- Optional spread-spectrum technique to reduce EMI
- Phase control for optimized EMI
- · Synchronous rectification
- Current mode loop with PI compensator
- Soft start
- Power Good flag with maskable interrupt
- Power Good signal (PGOOD) with selectable sources
- Average output current sensing (for PFM entry and load current measurement)

The following parameters can be programmed through the registers, the default values are set by OTP bits:

- · Output voltage
- Forced PWM operation
- Switch current limit
- · Output voltage slew rate
- Enable and disable delays

There are two modes of operation for the buck converter, depending on the output current required: pulse-width modulation (PWM) and pulse-frequency modulation (PFM). The converter operates in PWM mode at high load currents of approximately 600 mA or higher. Lighter output current loads cause the converter to automatically switch into PFM mode for reduced current consumption when forced PWM mode is disabled. The forced PWM mode can be selected to maintain fixed switching frequency at all load current levels.

A block diagram of a single core is shown in \bigseparty 7-1.



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图 7-1. Detailed Block Diagram Showing One Core

7.3.1.2 Transition Between PWM and PFM Modes

The PWM mode operation optimizes efficiency at mid to full load at the expense of light-load efficiency. The LP87332D-Q1 converter operates in the PWM mode at load current of about 600 mA or higher. At lighter load current levels the device automatically switches into the PFM mode for reduced current consumption when forced PWM mode is disabled (AUTO mode operation). By combining the PFM and the PWM modes, a high efficiency is achieved over a wide output-load current range.

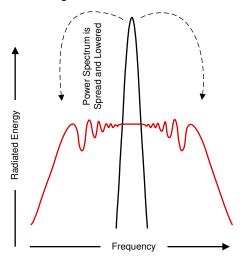
7.3.1.3 Buck Converter Load Current Measurement

The buck load current can be monitored through I^2C registers. The monitored buck converter is selected with the LOAD_CURRENT_BUCK_SELECT bit in the SEL_I_LOAD register. A write to this selection register starts a current measurement sequence. The regulator is automatically forced to the PWM mode for the measurement period. The measurement sequence is 50 μ s long, maximum.

The LP87332D-Q1 device can be configured to give out an interrupt (the I_MEAS_INT bit in the INT_TOP_1 register) after the load current measurement sequence is finished. The load current measurement interrupt can be masked with the I_MEAS_MASK bit (TOP_MASK_1 register). The measurement result can be read from the registers I_LOAD_1 and I_LOAD_2. The register I_LOAD_1 bits BUCK_LOAD_CURRENT[7:0] gives out the LSB bits, and the register I_LOAD_2 bit BUCK_LOAD_CURRENT[8] gives out the MSB bit. The measurement result BUCK_LOAD_CURRENT[8:0] LSB is 20 mA, and the maximum code value of the measurement corresponds to 10.22 A.

7.3.1.4 Spread-Spectrum Mode

Systems with periodic switching signals may generate a large amount of switching noise in a set of narrowband frequencies (the switching frequency and its harmonics). The usual solution to reduce noise coupling is to add EMI-filters and shields to the boards. The LP87332D-Q1 has a register-selectable spread-spectrum mode which minimizes the need for output filters, ferrite beads, or chokes. In spread spectrum mode, the switching frequency varies around the center frequency, reducing the EMI emissions radiated by the converter and associated passive components and PCB traces (see Spread-Spectrum Modulation). Spread-spectrum mode is only available when an internal RC oscillator is used (EN_PLL bit is 0 in PLL_CTRL register), it is enabled with the EN SPREAD SPEC bit in the CONFIG register, and it affects both buck cores.



Where a fixed frequency converter exhibits large amounts of spectral energy at the switching frequency, the spread spectrum architecture of the LP87332D-Q1 spreads that energy over a large bandwidth.

图 7-2. Spread-Spectrum Modulation

7.3.2 Sync Clock Functionality

The LP87332D-Q1 device contains a CLKIN input to synchronize the switching clock of the buck regulators with the external clock. The block diagram of the clocking and PLL module is shown in 图 7-3. Depending on the EN_PLL bit in the PLL_CTRL register and the external clock availability, the external clock is selected and interrupt is generated as shown in 表 7-2. The interrupt can be masked with the SYNC_CLK_MASK bit in the TOP_MASK_1 register. The nominal frequency of the external input clock is set by the EXT_CLK_FREQ[4:0] bits in the PLL_CTRL register, and it can be from 1 MHz to 24 MHz with 1-MHz steps. The external clock must be inside accuracy limits (-30%/+10%) of the selected frequency for valid clock detection.

The SYNC_CLK_INT interrupt in the INT_TOP_1 register is also generated in cases where the external clock is expected but is not available. These cases occur when EN_PLL is 1 during start-up (read OTP-to-standby transition) and during Buck regulator enable (standby-to-active transition).

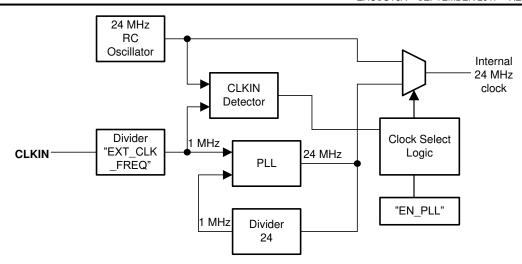


图 7-3. Clock and PLL Module

表 7-2. PLL Operation

FN PII			INTERRUPT FOR EXTERNAL CLOCK	сьоск			
STANDBY	0	Disabled	No	Internal RC			
ACTIVE	0	Disabled	No	Internal RC			
STANDBY	1	Enabled	When external clock appears or disappears	Automatic change to external clock when available			
ACTIVE	1	Enabled	When external clock appears or disappears	Automatic change to external clock when available			

7.3.3 Low-Dropout Linear Regulators (LDOs)

The LP87332D-Q1 device includes two identical linear regulators, LD00 and LD01, which target analog loads with low noise requirements. The LD0 regulators deliver 0.8-V to 3.3-V regulated voltage rails from a 2.5-V to 5.5-V input voltage. Both regulators have dedicated inputs which can be higher or lower than the device system voltage $V_{(VANA)}$ to minimize the power dissipation.

7.3.4 Power-Up

The power-up sequence for the LP87332D-Q1 is as follows:

- The VANA and VIN_Bx reach minimum recommended levels (V_{VANA} > VANA_{UVLO}). This initiates power-on-reset (POR), OTP reading, and enables the system I/O interface. The I²C host should allow at least 1.2 ms before writing or reading data to the LP87332D-Q1.
- · The device enters standby mode.
- The host can change the default register setting by I²C if needed.
- · The regulators can be enabled and disabled.
- The GPO signals can be controlled by the EN pin and the I²C interface.

Transitions between the operating modes are shown in # 7.4.1.



7.3.5 Regulator Control

7.3.5.1 Enabling and Disabling Regulators

The regulators can be enabled when the device is in STANDBY or ACTIVE state. There are two ways to enable and disable the buck regulators:

- Using the BUCKx_EN bit in the BUCKx_CTRL_1 register (the BUCKx_EN_PIN_CTRL bit is 0 in the BUCKx_CTRL_1 register).
- Using the EN control pin (the BUCKx_EN bit and the BUCKx_EN_PIN_CTRL bit is 1).

Similarly, there are two ways to enable and disable the LDO regulators:

- Using the LDOx_EN bit in the LDOx_CTRL register (the LDOx_EN_PIN_CTRL bit is 0 in the LDOx_CTRL register).
- Using the EN control pin (the LDOx EN bit is 1 and the LDOx EN PIN CTRL bit is 1).

If the EN control pin is used for enable and disable, then the following occurs:

- The delay from the control signal rising edge to start-up is set by the BUCKx_STARTUP_DELAY[3:0] bits in the BUCKx_DELAY register and the LDOx_STARTUP_DELAY[3:0] bits in the LDOx_DELAY register.
- The delay from the control signal falling edge to shutdown is set by the BUCKx_SHUTDOWN_DELAY[3:0] bits in the BUCKx_DELAY register and the LDOx_SHUTDOWN_DELAY[3:0] bits in the LDOx_DELAY register.

The delays are only valid for the EN signal transitions and not for control with I²C writings to the BUCKx_EN and the LDOx_EN bits.

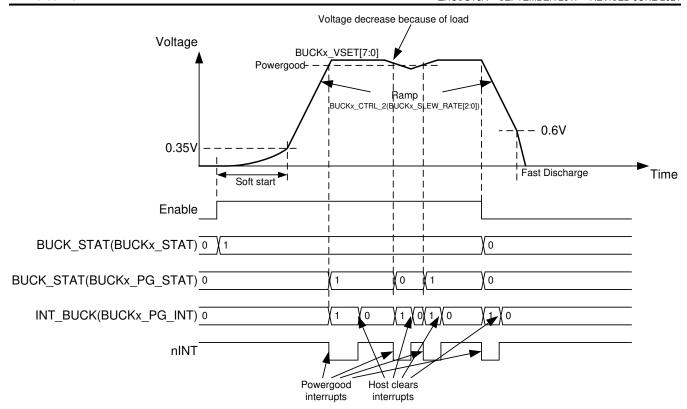
The control of the regulator (with 0-ms delays) is shown in 表 7-3.

表 7-3. Regulator Control

ger or regulator contact							
	BUCKx_EN AND LDOx_EN	BUCKx_EN_PIN_CTRL AND LDOx_EN_PIN_CTRL	EN PIN	BUCKx OUTPUT VOLTAGE AND LDOx OUTPUT VOLTAGE			
Enable and disable control	0	Don't Care	Don't Care	Disabled			
with the BUCKx_EN and the LDOx_EN bit	1	0	Don't Care	BUCKx_VSET[7:0] and LDOx_VSET[4:0]			
Enable and disable control	1	1	Low	Disabled			
with the EN pin	1	1	High	BUCKx VSET[7:0] and LDOx VSET[4:0]			

The buck regulator is enabled by the EN pin or by I²C writing as shown in 7-4. The soft-start circuit limits the in-rush current during start-up. When the output voltage rises to a 0.35-V level, the output voltage becomes slew-rate controlled. If there is a short circuit at the output, and the output voltage does not increase above the 0.35-V level in 1 ms or the output voltage drops below 0.35-V level during operation (for minimum of 1 ms), then the regulator is disabled, and the BUCKx_SC_INT interrupt in the INT_BUCK register is set. When the output voltage reaches the Power-Good threshold level, the BUCKx_PG_INT interrupt flag in the INT_BUCK register is set. The Power-Good interrupt flag, when reaching valid output voltage, can be masked using the BUCKx_PGR_MASK bit in the BUCK_MASK register. The Power-Good interrupt flag can also be generated when the output voltage becomes invalid. The interrupt mask for invalid output voltage detection is set by the BUCKx_PGF_MASK bit in the BUCK_MASK register. A BUCKx_PG_STAT bit in the BUCK_STAT register always shows the validity of the output voltage; 1 means valid and 0 means invalid output voltage. A PGOOD_WINDOW_BUCK bit in the PGOOD_CTRL_1 register sets the detection method for the valid buck output voltage, either undervoltage detection or undervoltage and overvoltage detection.

Product Folder Links: LP87332D-Q1



BUCK_MASK(BUCKx_PGF_MASK) = 0 BUCK_MASK(BUCKx_PGR_MASK) = 0

图 7-4. Buck Regulator Enable and Disable

The LDO regulator is enabled by the EN pin or by I²C writing, as shown in \$\below{\text{Z}}\$ 7-5. The soft-start circuit limits the in-rush current during start-up. The output voltage increase rate is less than 100 mV/µsec during soft-start. If there is a short circuit at the output, and the output voltage does not increase above the 0.3-V level in 1 ms or the output voltage drops below 0.3-V level during operation (for minimum of 1 ms), then the regulator is disabled, and the LDOx_SC_INT interrupt in the INT_LDO register is set. When the output voltage reaches the Power-Good threshold level, the LDOx_PG_INT interrupt flag in the INT_LDO register is set. The Power-Good interrupt flag, when reaching valid output voltage, can be masked using the LDOx_PGR_MASK bit in the LDO_MASK register. The Power-Good interrupt flag can also be generated when the output voltage becomes invalid. The interrupt mask for invalid output voltage detection is set by the LDOx_PGF_MASK bit in the LDO_MASK register. A LDOx_PG_STAT bit in the LDO_STAT register always shows the validity of the output voltage; 1 means valid, and 0 means invalid output voltage. A PGOOD_WINDOW_LDO bit in the PGOOD_CTRL_1 register sets the detection method for the valid LDO output voltage, either undervoltage detection or undervoltage and overvoltage detection.



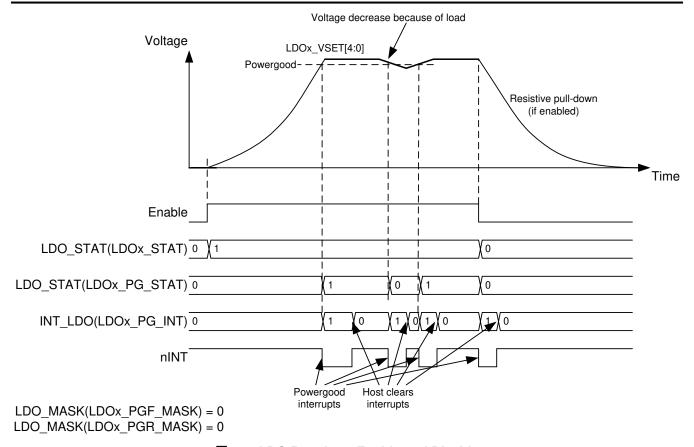


图 7-5. LDO Regulator Enable and Disable

The EN input pin has an integrated pulldown resistor. The pulldown resistor is controlled with the EN_PD bit in the CONFIG register.

7.3.5.2 Changing Output Voltage

The output voltage of the regulator can be changed by writing to the BUCKx_VOUT and LDOx_VOUT register. The voltage change for the buck regulator is always slew-rate controlled, and the slew-rate is defined by the BUCKx_SLEW_RATE[2:0] bits in the BUCKx_CTRL_2 register. During voltage change, the forced PWM mode is used automatically. When the programmed output voltage is achieved, the mode becomes the one defined by the load current, the BUCKx_FPWM bit in the BUCKx_CTRL_1 register.

The voltage change and Power-Good interrupts are shown in ₹ 7-6.



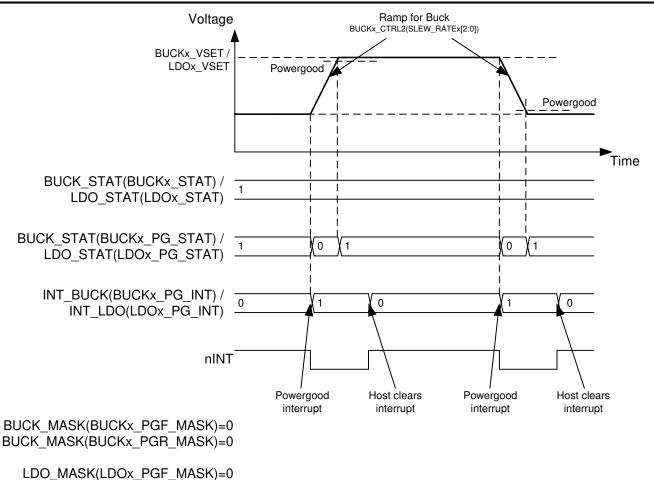


图 7-6. Regulator Output Voltage Change

During an LDO voltage change, the internal reference for the Power-Good detection is also changed. For this reason when the output voltage is changing, toggling of the Power-Good signal may still indicate a valid output. This period takes less than 100 µs and after that time the Power-Good gives correct value.

7.3.6 Enable and Disable Sequences

LDO MASK(LDOx PGR MASK)=0

The LP87332D-Q1 device supports start-up and shutdown sequencing with programmable delays for different regulator outputs using a single EN control signal. The Buck regulator is selected for delayed control with:

- The BUCKx EN = 1 in the BUCKx CTRL 1 register
- The BUCKx_EN_PIN_CTRL = 1 in the BUCKx_CTRL_1 register
- The BUCKx_VSET[7:0] bits in the BUCKx_VOUT register defines the voltage when the EN pin is high
- The delay from the rising edge of the EN pin to the regulator enable is set by the BUCKx_STARTUP_DELAY[3:0] bits in the BUCKx_DELAY register.
- The delay from the falling edge of the EN pin to the regulator disable is set by the BUCKx_SHUTDOWN_DELAY[3:0] bits in the BUCKx_DELAY register.

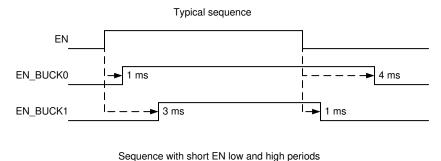
In the same way, the LDO regulator is selected for delayed control with:

- The LDOx EN = 1 in the LDOx CTRL register
- The LDOx EN PIN CTRL = 1 in the LDOx CTRL register
- The LDOx_VSET[4:0] bits in the LDOx_VOUT register defines the voltage when the EN pin is high
- The delay from the rising edge of the EN pin to the regulator enable is set by the LDOx_STARTUP_DELAY[3:0] bits in the LDOx_DELAY register.
- The delay from the falling edge of the EN pin to the regulator disable is set by the LDOx_SHUTDOWN_DELAY[3:0] bits in the LDOx_DELAY register.

The GPO and GPO2 digital output signals can be also controlled as a part of start-up and shutdown sequencing with the following settings:

- GPOx_EN = 1 in GPO_CTRL register
- GPOx_EN_PIN_CTRL = 1 in GPO_CTRL register
- The delay from the rising edge of the EN pin to the rising edge of the GPO or GPO2 signal is set by the GPOx_STARTUP_DELAY[3:0] bits in the GPOx_DELAY register.
- The delay from the falling edge of the EN pin to the falling edge of the GPO or GPO2 signal is set by the GPOx SHUTDOWN DELAY[3:0] bits in the GPOx DELAY register.

An example of the start-up and shutdown sequences for the buck regulators are shown in 2.7. The start-up and shutdown delays for the Buck0 regulator are 1 ms and 4 ms, and for the Buck1 regulator the start-up and shutdown delays are 3 ms and 1 ms. The delay settings are only used for enable or disable control with the EN signal.



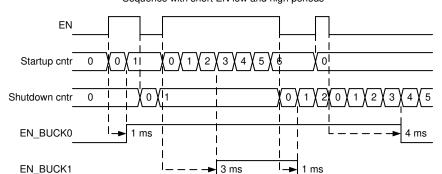


图 7-7. Start-Up and Shutdown Sequencing

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7.3.7 Device Reset Scenarios

There are two reset methods implemented on the LP87332D-Q1:

- Software reset with the SW_RESET bit in the RESET register.
- Undervoltage lockout (UVLO) reset from the VANA supply.

An software reset occurs when 1 is written to the SW_RESET bit. The bit is automatically cleared after writing. This event disables all the regulators immediately, drives the GPO or GPO2 signals low, resets all the register bits to the default values, and loads the OTP bits (see 7-13). The I²C interface is not reset during a software reset.

If the VANA supply voltage falls below the UVLO threshold level, then all the regulators are disabled immediately, the GPO or GPO2 signals are driven low, and all the register bits are reset to the default values. When the VANA supply voltage transitions above the UVLO threshold level, an internal POR occurs. The OTP bits are loaded to the registers and a startup is initiated according to the register settings.

7.3.8 Diagnosis and Protection Features

The LP87332D-Q1 is capable of providing four levels of protection features:

- Information of valid regulator output voltage, which sets the interrupt or PGOOD signal.
- · Warnings for diagnosis, which sets the interrupt.
- · Protection events, which are disabling the regulators.
- Faults, which are causing the device to shutdown.

The LP87332D-Q1 sets the flag bits indicating what protection or warning conditions have occurred, and the nINT pin is pulled low. The nINT is released again after a clear of flags is complete. The nINT signal stays low until all the pending interrupts are cleared.

When a fault is detected or software requested reset, it is indicated by a RESET_REG_INT interrupt flag in the INT_TOP_2 register after next start-up. If the RESET_REG_MASK is set to masked in the OTP, then the interrupt is not generated. The mask bit change with I²C does not affect, because the RESET_REG_MASK bit is loaded from the OTP during reset sequence.



表 7-4. Summary of Interrupt Signals

EVENT	DEVICE RESPONSE	INTERRUPT BIT	INTERRUPT MASK BIT	STATUS BIT	RECOVERY AND INTERRUPT CLEAR
Buck current limit triggered	No effect	BUCK_INT BUCKx_ILIM_INT	BUCKx_ILIM_MASK	BUCKx_ILIM_STAT	Write 1 to the BUCKx_ILIM_INT bit. Interrupt is not cleared if the current limit is active
LDO current limit triggered	No effect	LDO_INT LDOx_ILIM_INT	LDOx_ILIM_MASK	LDOx_ILIM_STAT	Write 1 to the LDOx_ILIM_INT bit Interrupt is not cleared if the current limit is active
Buck short circuit (V _{VOUT} < 0.35 V at 1 ms after enable) or overload (V _{VOUT} decreasing below 0.35 V during operation, 1-ms debounce)	Regulator disable	BUCK_INT BUCKX_SC_INT	N/A	N/A	Write 1 to the BUCKx_SC_INT bit
LDO short circuit (V _{VOUT} < 0.3 V at 1 ms after enable) or overload (V _{VOUT} decreasing below 0.3 V during operation, 1-ms debounce)	Regulator disable	LDO_INT LDOx_SC_INT	N/A	N/A	Write 1 to the LDOx_SC_INT bit
Thermal warning	No effect	TDIE_WARN_INT	TDIE_WARN_MASK	TDIE_WARN_STAT	Write 1 to tge TDIE_WARN_INT bit Interrupt is not cleared if the temperature is above the thermal warning level
Thermal shutdown	All the regulators are disabled immediately, and the GPO and GPO2 are set to low	TDIE_SD_INT	N/A	TDIE_SD_STAT	Write 1 to the TDIE_SD_INT bit Interrupt is not cleared if the temperature is above the thermal shutdown level
VANA overvoltage (VANA _{OVP})	All the regulators are disabled immediately, and the GPO and GPO2 are set to low	OVP_INT	N/A	OVP_STAT	Write 1 to the OVP_INT bit Interrupt is not cleared if the VANA voltage is above the VANA _{OVP} level
Buck power good, output voltage becomes valid	No effect	BUCK_INT BUCKx_PG_INT	BUCKx_PGR_MASK	BUCKx_PG_STAT	Write 1 to the BUCKx_PG_INT bit
Buck power good, output voltage becomes invalid	No effect	BUCK_INT BUCKx_PG_INT	BUCKx_PGF_MASK	BUCKx_PG_STAT	Write 1 to the BUCKx_PG_INT bit
LDO Power good, output voltage becomes valid	No effect	LDO_INT LDOx_PG_INT	LDOx_PGR_MASK	LDOx_PG_STAT	Write 1 to the LDOx_PG_INT bit
LDO power good, output voltage becomes invalid	No effect	LDO_INT LDOx_PG_INT	LDOx_PGF_MASK	LDOx_PG_STAT	Write 1 to the LDOx_PG_INT bit
PGOOD pin changing from active to inactive state ⁽¹⁾	No effect	PGOOD_INT	PGOOD_MASK	PGOOD_STAT	Write 1 to the PGOOD_INT bit
External clock appears or disappears	No effect to regulators	SYNC_CLK_INT(2)	SYNC_CLK_MASK	SYNC_CLK_STAT	Write 1 to the SYNC_CLK_INT bit
Load current measurement is ready	No effect	I_MEAS_INT	I_MEAS_MASK	N/A	Write 1 to the I_MEAS_INT bit
Supply voltage VANA _{UVLO} triggered (VANA falling)	Immediate shutdown and the registers reset to default values	N/A	N/A	N/A	N/A
Supply voltage VANA _{UVLO} triggered (VANA rising)	Startup and the registers reset to default values and the OTP bits are loaded	RESET_REG_INT	RESET_REG_MASK	N/A	Write 1 to the RESET_REG_INT bit
Software requested reset	Immediate shutdown is followed by power up and the registers are reset to their default values	RESET_REG_INT	RESET_REG_MASK	N/A	Write 1 to the RESET_REG_INT bit

The PGOOD_STAT bit is 1 when the PGOOD pin shows valid voltages. The PGOOD_POL bit in the PGOOD_CTRL_1 register affects only the PGOOD pin polarity, not the Power Good and PGOOD_INT interrupt polarity.

If the clock is not available when the clock detector is enabled, then an interrupt is generated during the clock-dector operation.



7.3.8.1 Power-Good Information (PGOOD pin)

In addition to the interrupt-based indication of the current limit and the Power-Good level, the LP87332D-Q1 device supports monitoring with PGOOD signal:

- · Regulator output voltage
- Input supply overvoltage
- Thermal warning
- Thermal shutdown

The regulator output voltage monitoring (not current limit monitoring) can be selected for the PGOOD indication. This selection is individual for both buck regulators and LDO regulators, and is set by the EN_PGOOD_BUCKx bits in the PGOOD_CTRL_1 register and the EN_PGOOD_LDOx bits in the PGOOD_CTRL_1 register. When a regulator is disabled, the monitoring is automatically masked to prevent it forcing the PGOOD inactive. A thermal warning can also be selected for the PGOOD indication with the EN_PGOOD_TWARN bit in the PGOOD_CTRL_2 register. The monitoring from all the output rails, thermal warning (TDIE_WARN_STAT), input overvoltage interrupt (OVP_INT), and thermal shutdown interrupt (TDIE_SD_INT) are combined, and the PGOOD pin is active only if all the selected sources shows a valid status.

The type of output voltage monitoring for the PGOOD signal is selected by the PGOOD_WINDOW_x bits in the PGOOD_CTRL_1 register. If the bit is 0, only undervoltage is monitored; if the bit is 1, both undervoltage and overvoltage are monitored.

The polarity and the output type (push-pull or open-drain) are selected by the PGOOD_POL and PGOOD_OD bits in the PGOOD_CTRL_1 register.

The PGOOD is only *active* and *asserted* when all enabled power resource output voltages are within specified tolerance for each requested and programmed output voltage.

The PGOOD is *inactive* and *de-asserted* if any enabled power resource output voltages is outside specified tolerance for each requested and programmed output voltage.

The device OTP setting selects either gated (or *unusual*) or continuous (or *invalid*) mode of operation.

7.3.8.1.1 PGOOD Pin Gated Mode

The gated (or *unusual*) mode of operation is selected by setting the PGOOD_MODE bit to 0 in the PGOOD CTRL 2 register.

For the gated mode of operation, the PGOOD behaves as follows:

- PGOOD is set to active or asserted state upon exiting the OTP configuration as an initial default state.
- PGOOD status is suspended or unchanged during an 800-µs gated time period, thereby *gating-off* the status indication.
- During normal power-up sequencing and requested voltage changes, the PGOOD state is not changed during an 800-µs gated time period. It typically remains *active* or *asserted* for normal conditions.
- During an *abnormal* power-up sequencing and requested voltage changes, the PGOOD status could change to *inactive* or *de-asserted* after an 800-µs gated time period if any output voltage is outside of regulation range.
- Using the gated mode of operation could allow the PGOOD signal to initiate an immediate power shutdown sequence if the PGOOD signal is wired-OR with signal connected to the EN input. This type of circuit configuration provides a smart PORz function for processor that eliminates the need for additional components to generate PORz upon start-up and to monitor voltage levels of key voltage domains.

Each detected fault sets the correcting fault bit in the PG_FAULT register to 1. The detected fault must be cleared to continue the PGOOD monitoring. The overvoltage and thermal shutdown are cleared by writing 1 to the OVP_INT and TDIE_SD_INT interrupt bits in the INT_TOP_1 register. The regulator fault is cleared by writing 1 to the corresponding register bit in the PG_FAULT register. The interrupts can also be cleared with the VANA UVLO by toggling the input supply. An example of the PGOOD pin operation in gated mode is shown in 图 7-8.

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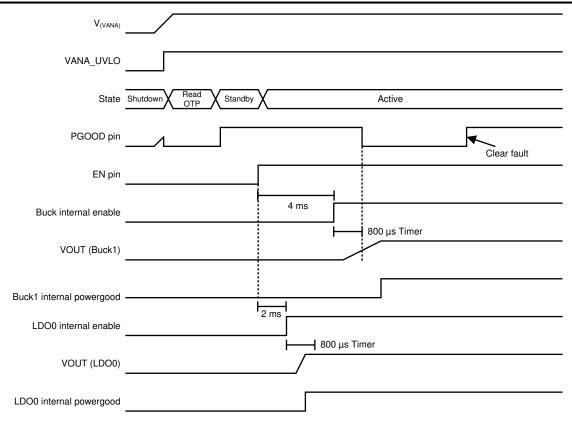


图 7-8. PGOOD Pin Operation in Gated Mode

7.3.8.1.2 PGOOD Pin Continuous Mode

The continuous (or *invalid*) mode of operation is selected by setting the PGOOD_MODE bit to 1 in the PGOOD_CTRL_2 register.

For the continuous mode of operation, PGOOD behaves as follows:

- PGOOD is set to active or asserted state upon exiting OTP configuration.
- PGOOD is set to inactive or de-asserted as soon as the regulator is enabled.
- PGOOD status begins indicating output voltage regulation status immediately and continuously.
- During power-up sequencing and requested voltage changes, PGOOD will toggle between *inactive* or *de-asserted* while output voltages are outside of regulation ranges and *active* or *asserted* when inside of regulation ranges.

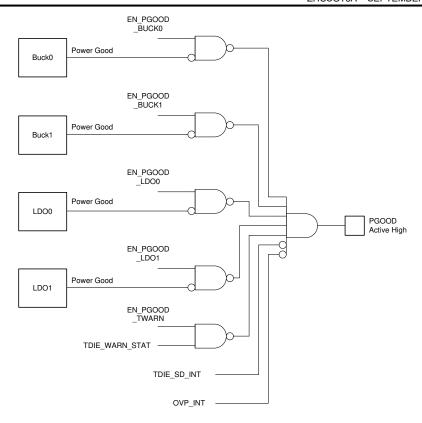
The PG_FAULT register bits are latched, and maintain the fault information until the host clears the fault bit by writing 1 to the bit. The PGOOD signal also indicates a thermal shutdown and input overvoltage interrupts, which are cleared by clearing the interrupt bits.

When the regulator voltage is transitioning from one target voltage to another, the PGOOD signal becomes inactive.

7.3.8.1.3 PGOOD Pin Inactive Mode

When the PGOOD signal becomes inactive, the source for the fault can be read from the PG_FAULT register. If the invalid output voltage becomes valid again, then the PGOOD signal becomes active. Thus the PGOOD signal always shows if the monitored output voltages are valid. The block diagram for this operation is shown in 27-9 and an example of operation is shown in 27-10.

The PGOOD signal can also be configured so that it maintains an inactive state even when the monitored outputs are valid, but there are PG_FAULT_x bits in the PG_FAULT register pending clearance. This type of operation is selected by setting the PGFAULT GATES PGOOD bit to 1 in the PGOOD CTRL 2 register.



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图 7-9. PGOOD Block Diagram (Continuous Mode)

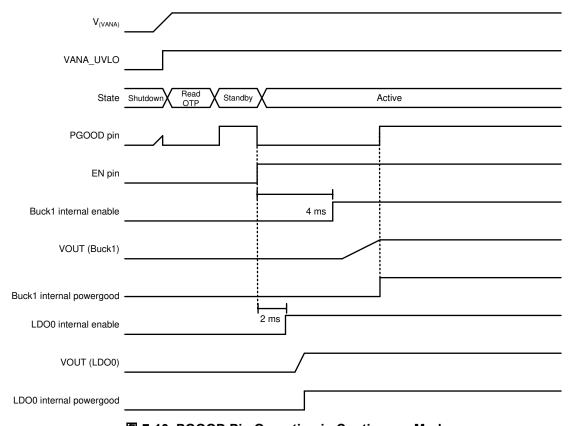


图 7-10. PGOOD Pin Operation in Continuous Mode

7.3.8.2 Warnings for Diagnosis (Interrupt)

7.3.8.2.1 Output Power Limit

The Buck regulators have programmable output peak current limits. The limits are individually programmed for both regulators with the BUCKx_ILIM[2:0] bits in the BUCKx_CTRL_2 register. If the load current is increased so that the current limit is triggered, then the regulator continues to regulate at the limit current level (peak current regulation). The voltage may decrease if the load current is higher than the limit current. If the current regulation continues for 20 µs, than the LP87332D-Q1 device sets the BUCKx_ILIM_INT bit in the INT_BUCK register and pulls the nINT pin low. The host processor can read the BUCKx_ILIM_STAT bits in the BUCK_STAT register to see if the regulator is still in peak current regulation mode, and the interrupt is cleared by writing 1 to the BUCKx_ILIM_INT bit. The current limit interrupt can be masked by setting the BUCKx_ILIM_MASK bit in the BUCK_MASK register to 1. The Buck overload situation is shown in 8 7-11.

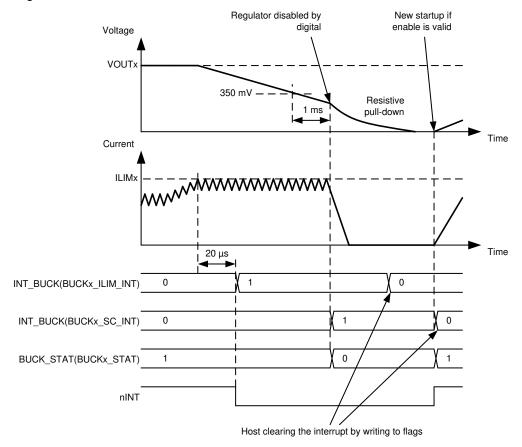


图 7-11. Buck Regulator Overload Situation

The LDO regulators also include current limit circuitry. If the load current is increased so that the current limit is triggered, the regulator limits the output current to the threshold level. The voltage may decrease if the load current is higher than the current limit. If the current regulation continues for 20 µs, the LP87332D-Q1 device sets the LDOx_ILIM_INT bit in the INT_LDO register and pulls the nINT pin low. The host processor can read the LDOx_ILIM_STAT bits in the LDO_STAT register to see if the regulator is still in current regulation mode and the interrupt is cleared by writing 1 to the LDOx_ILIM_INT bit. The current limit interrupt can be masked by setting the LDOx_ILIM_MASK bit in the LDO_MASK register to 1. The LDO overload situation is shown in $\[mathbb{R}\]$ 7-12.

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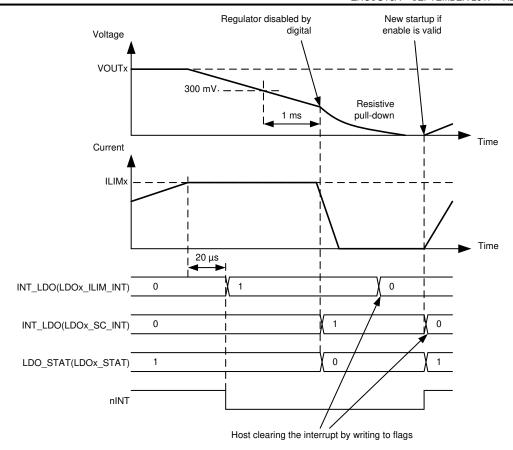


图 7-12. LDO Regulator Overload Situation

7.3.8.2.2 Thermal Warning

The LP87332D-Q1 device includes a protection feature against overtemperature by setting an interrupt for the host processor. The threshold level of the thermal warning is selected with the TDIE_WARN_LEVEL bit in the CONFIG register.

If the LP87332D-Q1 device temperature increases above the thermal warning level, then the device sets the TDIE_WARN_INT bit in the INT_TOP_1 register and pulls the nINT pin low. The status of the thermal warning can be read from the TDIE_WARN_STAT bit in the TOP_STAT register, and the interrupt is cleared by writing 1 to the TDIE_WARN_INT bit. The thermal warning interrupt can be masked by setting the TDIE_WARN_MASK bit in the TOP_MASK_1 register to 1.

7.3.8.3 Protection (Regulator Disable)

If the regulator is disabled, because of protection or fault (short-circuit protection, overload protection, thermal shutdown, input overvoltage protection, or UVLO), then the output power FETs are set to high-impedance mode and the output pulldown resistor is enabled (if enabled with the BUCKx_RDIS_EN bit in the BUCKx_CTRL_1 register and the LDOx_RDIS_EN bit in the LDOx_CTRL register). The turnoff time of the output voltage is defined by the output capacitance, load current, and resistance of the integrated pull-down resistor. The pull-down resistors are active as long as the VANA voltage is above approximately a 1.2-V level.

7.3.8.3.1 Short-Circuit and Overload Protection

A short-circuit protection feature allows the LP87332D-Q1 to protect itself and the external components against a short circuit at the output or against overload during start-up. For the buck and LDO regulators, the fault thresholds are about 350 mV (buck) and 300 mV (LDO). The protection is triggered and the regulator is disabled if the output voltage is below the threshold level (1 ms) after the regulator is enabled.

In a similar way, the overload situation is protected during normal operation. If the output voltage falls below 0.35 V and 0.3 V and remains below the threshold level for 1 ms, then the regulator is disabled.

In Buck regulator short-circuit and overload situations, the BUCKx_SC_INT bit in the INT_BUCK register and the INT_BUCKx bit in the INT_TOP_1 register are set to 1, the BUCKx_STAT bit in BUCK_STAT register is set to 0, and the nINT signal is pulled low. In LDO regulator short-circuit and overload situations, the LDOx SC INT bit in the INT_LDO register and the INT_LDOx bit in the INT_TOP_1 register are set to 1, the LDOx_STAT bit in the LDO STAT register is set to 0, and the nINT signal is pulled low. The host processor clears the interrupt by writing 1 to the BUCKx_SC_INT or to the LDOx_SC_INT bit. Upon clearing the interrupt, the regulator makes a new start-up attempt if the regulator is in an enabled state.

7.3.8.3.2 Overvoltage Protection

The LP87332D-Q1 device monitors the input voltage from the VANA pin in standby and active operation modes. If the input voltage rises above the VANA_{OVP} voltage level, the following occurs:

- All regulators are disabled immediately (without switching ramp or shutdown delays).
- The pull-down resistors discharge the output voltages, if the pull-down resistors are enabled (the BUCKx RDIS EN = 1 in the BUCKx CTRL 1 register and the LDOx RDIS EN = 1 in the LDOx CTRL register).
- The GPOs are set to logic low level.
- The nINT signal is pulled low.
- The OVP INT bit in the INT TOP 1 register is set to 1.
- The BUCKx STAT bit in the BUCK STAT register and the LDOx STAT bit in the LDO STAT register are set

The host processor clears the interrupt by writing 1 to the OVP INT bit. If the input voltage is above the overvoltage detection level, then the interrupt is not cleared. The host can read the status of the overvoltage from the OVP STAT bit in the TOP STAT register. The regulators cannot be enabled as long as the input voltage is above the overvoltage detection level or while the overvoltage interrupt is pending.

7.3.8.3.3 Thermal Shutdown

The LP87332D-Q1 has an overtemperature protection function that operates to protect itself from short-term misuse and overload conditions. When the junction temperature exceeds around 150°C, the regulators are disabled immediately (without switching ramp and shutdown delays), the TDIE SD INT bit in the INT TOP 1 register is set to 1, the nINT signal is pulled low, and the device enters STANDBY. The nINT is cleared by writing 1 to the TDIE SD INT bit. If the temperature is above thermal shutdown level, then the interrupt is not cleared. The host can read the status of the thermal shutdown from the TDIE SD STAT bit in the TOP STAT register. The regulators cannot be enabled as long as the junction temperature is above the thermal shutdown level or while the thermal shutdown interrupt is pending.

Product Folder Links: LP87332D-Q1

7.3.8.4 Fault (Power Down)

7.3.8.4.1 Undervoltage Lockout

When the input voltage falls below the VANA $_{UVLO}$ at the VANA pin, the buck and LDO regulators are disabled immediately (without switching ramp and shutdown delays), the output capacitor is discharged using the pulldown resistor, and the LP87332D-Q1 device enters SHUTDOWN. When the $V_{(VANA)}$ voltage is above the VANA $_{UVLO}$ threshold level, the device powers up to STANDBY state.

If the reset interrupt is unmasked by default (OTP bit for RESET_REG_MASK is 0 in TOP_MASK_2 register), then the RESET_REG_INT interrupt bit in the INT_TOP_2 register indicates that the device has been in SHUTDOWN. The host processor must clear the interrupt by writing 1 to the RESET_REG_INT bit. If the host processor reads the RESET_REG_INT interrupt bit after detecting an nINT low signal, then it detects that the input supply voltage has been below the VANA_{UVLO} level (or the host has requested reset with the SW_RESET bit in the RESET register), and the registers are reset to default values.

7.3.9 Operation of the GPO Signals

The LP87332D-Q1 device supports up to two general purpose output signals, GPO and GPO2. The GPO2 signal is multiplexed with the CLKIN signal. The selection between the CLKIN and GPO2 pin function is set with the CLKIN_PIN_SEL bit in the CONFIG register.

The GPO pins are configured with the following bits:

The GPOx_OD bit in The GPO_CTRL register defines the type of the output, either push-pull with V_(VANA) level or open drain.

The logic level of the GPOx pin is set by the EN_GPOx bit in the GPO_CTRL register.

The control of the GPOs can be included to start-up and shutdown sequences. The GPO control for a sequence with an EN pin is selected by the GPOx_EN_PIN_CTRL bit in the GPO_CTRL register. For start-up and shutdown sequence control, see #7.3.6.

7.3.10 Digital Signal Filtering

The digital signals have a debounce filtering. The signal or supply is sampled with a clock signal and a counter. This results as an accuracy of one clock period for the debounce window.

表 7-5. Digital Signal Filtering

X 7 or 2 ignar 5 ignar 7 incoming							
EVENT	SIGNAL/SUPPLY	RISING EDGE	FALLING EDGE				
EVENT	SIGNAL/SUFFLI	LENGTH	LENGTH				
Enable/disable for BUCKx, LDOx or GPOx	EN	3 μs ⁽¹⁾	3 µs ⁽¹⁾				
VANA UVLO	VANA	3 μs ⁽¹⁾ (VANA voltage rising)	Immediate (VANA voltage falling)				
VANA overvoltage	VANA	1 μs (VANA voltage rising)	20 μs (VANA voltage falling)				
Thermal warning	TDIE_WARN_INT	20 µs	20 µs				
Thermal shutdown	TDIE_SD_INT	20 µs	20 µs				
Current limit	VOUTx_ILIM	20 µs	20 µs				
Overload	FB_B0, FB_B1, VOUT_LDO0, VOUT_LDO1	1 ms	N/V				
PGOOD pin and power-good interrupt	PGOOD / FB_B0, FB_B1, VOUT_LDO0, VOUT_LDO1	6 µs	6 µs				

(1) No glitch filtering, only synchronization.



7.4 Device Functional Modes

7.4.1 Modes of Operation

 $\textbf{SHUTDOWN:} \ \ \text{The V}_{(VANA)} \ \ \text{voltage is below VANA}_{UVLO} \ \ \text{threshold level. All switch, reference, control, and bias}$

circuitry of the LP87332D-Q1 device are turned off.

READ OTP: The main supply voltage V_(VANA) is above VANA_{UVLO} level. The regulators are disabled, and

the reference and bias circuitry of the LP87332D-Q1 are enabled. The OTP bits are loaded to

registers.

STANDBY: The main supply voltage $V_{(VANA)}$ is above VANA_{UVLO} level. The regulators are disabled, and

the reference, control, and bias circuitry of the LP87332D-Q1 are enabled. All registers can be read or written by the host processor through the system serial interface. The regulators can be

enabled if needed.

ACTIVE: The main supply voltage $V_{(VANA)}$ is above VANA_{UVLO} level. At least one regulator is enabled. All

registers can be read or written by the host processor through the system serial interface.

The operating modes and transitions between the modes are shown in $\boxed{8}$ 7-13.

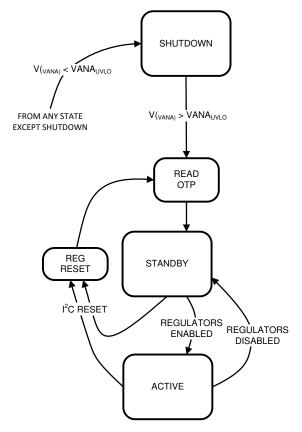


图 7-13. Device Operation Modes

7.5 Programming

7.5.1 I²C-Compatible Interface

The I²C-compatible synchronous serial interface provides access to the programmable functions and registers on the device. This protocol uses a two-wire interface for bidirectional communications between the ICs connected to the bus. The two interface lines are the serial data line (SDA), and the serial clock line (SCL). Every device on the bus is assigned a unique address, and acts as either a master or a slave depending on whether it generates or receives the serial clock SCL. The SCL and SDA lines must each have a pullup resistor placed on the line and remain HIGH even when the bus is idle. The LP87332D-Q1 supports standard mode (100 kHz), fast mode (400 kHz), fast mode plus (1 MHz), and high-speed mode (3.4 MHz).

7.5.1.1 Data Validity

The data on the SDA line must be stable during the HIGH period of the clock signal (SCL). In other words, the state of the data line can only be changed when clock signal is LOW.

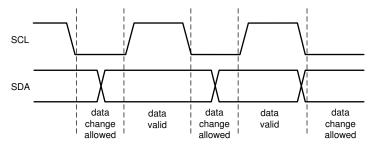


图 7-14. Data Validity Diagram

7.5.1.2 Start and Stop Conditions

The LP87332D-Q1 is controlled through an I^2 C-compatible interface. START and STOP conditions classify the beginning and end of the I^2 C session. A START condition is defined as SDA transitions from HIGH to LOW while SCL is HIGH. A STOP condition is defined as an SDA transition from LOW to HIGH while SCL is HIGH. The I^2 C master always generates the START and STOP conditions.

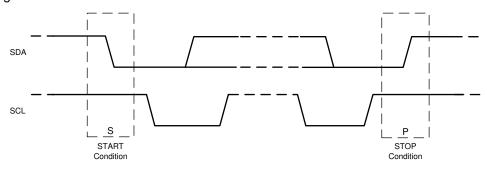


图 7-15. Start and Stop Sequences



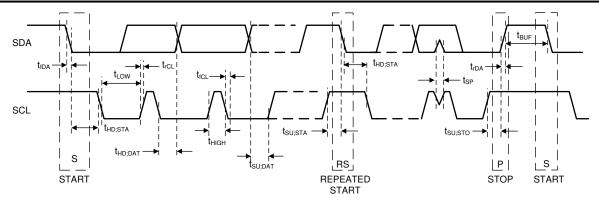


图 7-16. I²C-Compatible Timing

7.5.1.3 Transferring Data

Every byte put on the SDA line must be eight bits long, with the most significant bit (MSB) transferred first. Each byte of data has to be followed by an acknowledge bit. The acknowledge-related clock pulse is generated by the master. The master releases the SDA line (HIGH) during the acknowledge clock pulse. The LP87332D-Q1 pulls down the SDA line during the 9th clock pulse, signifying an acknowledge. The LP87332D-Q1 generates an acknowledge after each byte has been received.

There is one exception to the acknowledge after every byte rule. When the master is the receiver, it must indicate to the transmitter an end of data by not-acknowledging (negative acknowledge) the last byte clocked out of the slave. This negative acknowledge still includes the acknowledge clock pulse (generated by the master), but the SDA line is not pulled down.

Note

If the $V_{(VANA)}$ voltage is below the VANA_{UVLO} threshold level during I²C communication, the LP87332D-Q1 device does not drive SDA line. The ACK signal and data transfer to the master is disabled at that time.

After the START condition, the bus master sends a chip address. This address is seven bits long, followed by an eighth bit, which is a data direction bit (READ or WRITE). For the eighth bit, a 0 indicates a WRITE, and a 1 indicates a READ. The second byte selects the register to which the data will be written. The third byte contains data to write to the selected register.

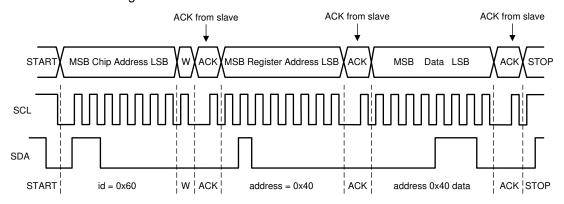
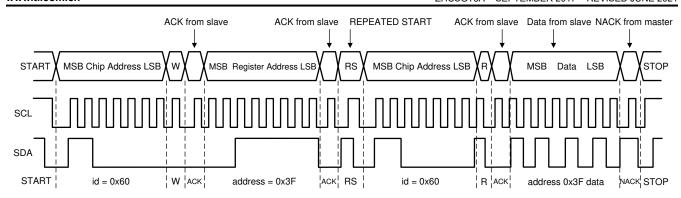


图 7-17. Write Cycle (w = write; SDA = 0). Example Device Address = 0x60



When READ function is to be accomplished, a WRITE function must precede the READ function as shown above.

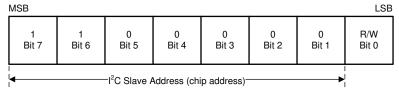
图 7-18. Read Cycle (r = read; SDA = 1). Example Device Address = 0x60

7.5.1.4 I²C-Compatible Chip Address

Note

The device address for the LP87332D-Q1 is 0x60.

After the START condition, the I^2C master sends the 7-bit address followed by an eighth bit, read or write (R/W). R/W = 0 indicates a WRITE and R/W = 1 indicates a READ. The second byte following the device address selects the register address to which the data is written. The third byte contains the data for the selected register.



Here in an example with device address of 1100000Bin = 60Hex.

图 7-19. Device Address Example

7.5.1.5 Auto-Increment Feature

The auto-increment feature allows writing several consecutive registers within one transmission. Every time an 8-bit word is sent to the LP87332D-Q1, the internal address index counter is incremented by one and the next register is written. 表 7-6 shows writing sequence to two consecutive registers. The auto-increment feature does not work for read.

表 7-6. Auto-Increment Example

MASTER ACTION	START	DEVICE ADDRESS = 0x60	WRITE		REGISTER ADDRESS		DATA		DATA		STOP	
LP87332D-Q1				ACK		ACK		ACK		ACK		



7.6 Register Maps

7.6.1 Register Descriptions

The LP87332D-Q1 is controlled by a set of registers through the I^2 C-compatible interface. The device registers addresses and abbreviations are listed in $\frac{1}{8}$ 7-7. A more detailed description is given in the $\frac{1}{8}$ 7.6.1.1 to $\frac{1}{8}$ 7.6.1.39 sections.

The asterisk (*) marking indicates register bits which are updated from OTP memory during READ OTP state.

Note

This register map describes the default values for a device with orderable code of LP87332DRHDRQ1. For other device versions the default values read from OTP memory can be different.

表 7-7. Summary of LP87332D-Q1 Control Registers

Addr	Register	Read / Write	D7	D6	D5	D4	D3	D2	D1	D0	
0x00	DEV_REV	R	DEVICE	 E_ID[1:0]			Reserved	do not use			
0x01	OTP_REV	R				OTP_	ID[7:0]				
0x02	BUCK0_ CTRL_1	R/W		Reserved -	- do not use		BUCK0_FP WM	BUCK0_RDI S_EN	BUCK0_ EN_PIN_CT RL	BUCK0_EN	
0x03	BUCK0_ CTRL_2	R/W	Reserved -	- do not use	E	BUCK0_ILIM[2:	0]	BUCK0_SLEW_RATE[2:0]			
0x04	BUCK1_ CTRL_1	R/W		Reserved -	do not use		BUCK1_FP WM	BUCK1_RDI S_EN	BUCK1_ EN_PIN_CT RL	BUCK1_EN	
0x05	BUCK1_ CTRL_2	R/W	Reserved -	- do not use	E	BUCK1_ILIM[2:	0]	BUCK	(1_SLEW_RAT	E[2:0]	
0x06	BUCK0_ VOUT	R/W	BUCK0_VSET					1			
0x07	BUCK1_ VOUT	R/W		BUCK1_VSET[7							
0x08	LDO0_ CTRL	R/W		Reserved - do not use					LDO0_ EN_PIN_CT RL	LDO0_EN	
0x09	LDO1_ CTRL	R/W		Reserved - do not use					LDO1_ EN_PIN_CT RL	LDO1_EN	
0x0A	LDO0_ VOUT	R/W	Res	served - do not	use		L	DO0_VSET[4:	0]		
0x0B	LDO1_ VOUT	R/W	Res	served - do not	use		L	LDO1_VSET[4:0]			
0x0C	BUCK0_ DELAY	R/W	BU	JCK0_SHUTD]YAJBD_NWC	3:0]	E	BUCK0_START	UP_DELAY[3:	0]	
0x0D	BUCK1_ DELAY	R/W	BU	JCK1_SHUTD]YAJBD_NWC	3:0]	E	BUCK1_START	UP_DELAY[3:	0]	
0x0E	LDO0_ DELAY	R/W	LI	DO0_SHUTDO)WN_DELAY[3	:0]		LDO0_START	JP_DELAY[3:0]	
0x0F	LDO1_ DELAY	R/W	LI	DO1_SHUTDO)WN_DELAY[3	:0]		LDO1_START	JP_DELAY[3:0]	
0x10	GPO_ DELAY	R/W	GPO_SHUTDOWN_DELAY[3:0]					GPO_STARTU	JP_DELAY[3:0]		
0x11	GPO2_ DELAY	R/W	GPO2_SHUTDOWN_DELAY[3:0]					GPO2_START	UP_DELAY[3:0)]	
0x12	GPO_ CTRL	R/W	Reserved - do not use	GPO2_OD	GPO2_ EN_PIN_CT RL	GPO2_EN	Reserved - do not use	GPO_OD	GPO_ EN_PIN_CT RL	GPO_EN	
0x13	CONFIG	R/W	Reserved - do not use	STARTUP_D ELAY_SEL	SHUTDOW N_DELAY_S EL	CLKIN_PIN_ SEL	CLKIN_PD	EN_PD	TDIE _WARN _LEVEL	EN_ SPREAD _SPEC	

Product Folder Links: LP87332D-Q1

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表 7-7. Summary of LP87332D-Q1 Control Registers (continued)

					ZD-QT CO							
Addr	Register	Read / Write	D7	D6	D5	D4	D3	D2	D1	D0		
0x14	PLL_CTRL	R/W	Reserved - do not use	EN_PLL	Reserved - do not use		EX.	T_CLK_FREQ[[4:0]			
0x15	PGOOD_CT RL_1	R/W	PGOOD_PO L	PGOOD_OD	PGOOD_WI NDOW_LDO	PGOOD_WI NDOW_BUC K	EN_PGOOD _LDO1	EN_PGOOD _LDO0	EN_PGOOD _BUCK1	EN_PGOOD _BUCK0		
0x16	PGOOD_CT RL_2	R/W		Res	served - do not	use		EN_PGOOD _TWARN	PG_FAULT_ GATES_PG OOD	PGOOD_M ODE		
0x17	PG_FAULT	R		Reserved - do not use PG_FAULT_ PG_FAULT_ PG_FAULT_ LDO1								
0x18	RESET	R/W			Res	served - do not	use			SW_ RESET		
0x19	INT_TOP_1	R/W	PGOOD_ INT	INT_ LDO	INT_ BUCK	SYNC_ CLK_INT	TDIE_SD_IN T	TDIE_ WARN_INT	OVP_INT	I_MEAS_ INT		
0x1A	INT_TOP_2	R/W		Reserved - do not use								
0x1B	INT_BUCK	R/W	Reserved - do not use									
0x1C	INT_LDO	R/W	Reserved - do not use	LDO1_ PG_INT	LDO1_ SC_INT	LDO1_ ILIM_INT	Reserved - do not use	LDO0_ PG_INT	LDO0_ SC_INT	LDO0_ ILIM_INT		
0x1D	TOP_ STAT	R	PGOOD_ST AT	Reserved -	do not use	SYNC_CLK _STAT	TDIE_SD _STAT	TDIE_ WARN_ STAT	OVP_ STAT	Reserved - do not use		
0x1E	BUCK_STAT	R	BUCK1_ STAT	BUCK1_ PG_STAT	Reserved - do not use	BUCK1_ ILIM_STAT	BUCK0_ STAT	BUCK0_ PG_STAT	Reserved - do not use	BUCK0_ ILIM_STAT		
0x1F	LDO_STAT	R	LDO1_ STAT	LDO1_ PG_STAT	Reserved - do not use	LDO1_ ILIM_STAT	LDO0_ STAT	LDO0_ PG_STAT	Reserved - do not use	LDO0_ ILIM_STAT		
0x20	TOP_ MASK_1	R/W	PGOOD_ INT_MASK	Reserved -	do not use	SYNC_CLK _MASK	Reserved - do not use	TDIE_WARN _MASK	Reserved - do not use	I_MEAS_ MASK		
0x21	TOP_ MASK_2	R/W			Res	served - do not	use			RESET_ REG_MASK		
0x22	BUCK_MAS K	R/W	BUCK1_PG F_MASK	BUCK1_PG R_MASK	Reserved - do not use	BUCK1_ ILIM_ MASK	BUCK0_PG F_MASK	BUCK0_PG R_MASK	Reserved - do not use	BUCK0_ ILIM_ MASK		
0x23	LDO_MASK	R/W	LDO1_PGF_ MASK							LDO0_ ILIM_ MASK		
0x24	SEL_I_ LOAD	R/W		Reserved - do not use								
0x25	I_LOAD_2	R		Reserved - do not use								
0x26	I_LOAD_1	R				BUCK_LOAD_	CURRENT[7:0]				



7.6.1.1 DEV_REV

DEV_REV is shown in 表 7-9, Address: 0x00

表 7-8. DEV_REV Register

D7	D6	D5	D4	D3	D2	D1	D0
DEVIC	E_ID[1:0]			Reserved -	do not use		

表 7-9. DEV_REV Register Field Descriptions

Bits	Field	Type	Default	Description
7:6	DEVICE_ID[1:0]	R	0x0	Device specific ID code.
5:0	Reserved - do not use	R	00 0010	

7.6.1.2 OTP REV

OTP_REV is shown in 表 7-11, Address: 0x01

表 7-10. OTP_REV Register



表 7-11. OTP_REV Register Field Descriptions

Bits	Field	Type	Default	Description
7:0	OTP_ID[7:0]	R	0x2D	Identification Code of the OTP EPROM Version.

7.6.1.3 BUCK0_CTRL_1

BUCK0 CTRL 1 is shown in the 表 7-13, Address: 0x02

表 7-12. BUCK0_CTRL_1 Register

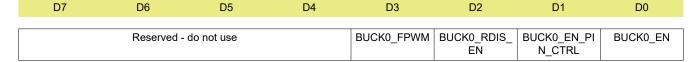


表 7-13. BUCK0_CTRL_1 Register Field Descriptions

Bits	Field	Type	Default	Description
7:4	Reserved - do not use	R/W	0000	
3	BUCK0_FPWM	R/W	0	Buck0 mode selection: 0 - Automatic transitions between the PFM and PWM modes (AUTO mode). 1 - Forced to PWM operation.
2	BUCK0_RDIS_EN	R/W	1	Enable output discharge resistor (R _{DIS_Bx}) when the Buck0 is disabled: 0 - Discharge resistor disabled. 1 - Discharge resistor enabled.
1	BUCK0_EN_PIN _CTRL	R/W	1	Enable control for the Buck0: 0 - only the BUCK0_EN bit controls the Buck0. 1 - BUCK0_EN bit <i>and</i> the EN pin control the Buck0.
0	BUCK0_EN	R/W	1	Enable the Buck0 regulator: 0 - Buck0 regulator is disabled. 1 - Buck0 regulator is enabled.

7.6.1.4 BUCK0_CTRL_2

BUCK0_CTRL_2 is shown in 表 7-15, Address: 0x03

表 7-14. BUCK0_CTRL_2 Register

Reserved -	- do not use		BUCK0_ILIM[2:0]		BUC	K0_SLEW_RATE	E[2:0]
D7	D6	D5	D4	D3	D2	D1	D0

表 7-15. BUCK0_CTRL_2 Register Field Descriptions

Bits	Field	Туре	Default	Description
7:6	Reserved - do not use	R/W	00	
5:3	BUCK0_ILIM[2:0]	R/W	0x5	Sets the switch current limit of Buck0. Can be programmed at any time during operation: 0x0 - 1.5 A 0x1 - 2.0 A 0x2 - 2.5 A 0x3 - 3.0 A 0x4 - 3.5 A 0x5 - 4.0 A 0x6 - Reserved - do not use. 0x7 - Reserved - do not use.
2:0	BUCK0_SLEW_RA TE[2:0]	R/W	0x2	Sets the output voltage slew rate for Buck0 regulator (rising and falling edges): 0x0 - Reserved - do not use. 0x1 - Reserved - do not use. 0x2 - 10 mV/µs 0x3 - 7.5 mV/µs 0x4 - 3.8 mV/µs 0x5 - 1.9 mV/µs 0x6 - 0.94 mV/µs 0x7 - 0.47 mV/µs

7.6.1.5 BUCK1_CTRL_1

BUCK1_CTRL_1 is shown in 表 7-17, Address: 0x04

表 7-16. BUCK1_CTRL_1 Register

יט	D6	D5	D4	D3	D2	וט	DU
	Reserved -	do not use		BUCK1_FPWM	BUCK1_RDIS_ EN	BUCK1_EN_PI N_CTRL	BUCK1_EN

表 7-17. BUCK1_CTRL_1 Register Field Descriptions

Bits	Field	Type	Default	Description
7:4	Reserved - do not use	R/W	0000	
3	BUCK1_FPWM	R/W	0	Buck1 mode selection: 0 - Automatic transitions between the PFM and PWM modes (AUTO mode). 1 - Forced to PWM operation.
2	BUCK1_RDIS_EN	R/W	1	Enable output discharge resistor (R _{DIS_Bx}) when the Buck1 is disabled: 0 - Discharge resistor is disabled. 1 - Discharge resistor is enabled.
1	BUCK1_EN_PIN _CTRL	R/W	1	Enable control for the Buck1: 0 - only the BUCK1_EN bit controls the Buck1 1 - BUCK1_EN bit and the EN pin control the Buck1.
0	BUCK1_EN	R/W	1	Enable the Buck1 regulator: 0 - Buck1 regulator is disabled. 1 - Buck1 regulator is enabled.

7.6.1.6 BUCK1_CTRL_2

BUCK1_CTRL_2 is shown in 表 7-19, Address: 0x05



表 7-18. BUCK1_CTRL_2 Register

D7	D6	D5	D4	D3	D2	D1	D0
			DUIGICA III INATO O		D.I.G	1/4 OLENA DATE	-ro o1
Reserved	- do not use		BUCK1 ILIM[2:0]		BUC	K1 SLEW RATE	=[2:0]

表 7-19. BUCK1_CTRL_2 Register Field Descriptions

Bits	Field	Type	Default	Description
7:6	Reserved - do not use	R/W	00	
5:3	BUCK1_ILIM[2:0]	R/W	0x5	Sets the switch current limit of the Buck1. Can be programmed at any time during operation: 0x0 - 1.5 A 0x1 - 2.0 A 0x2 - 2.5 A 0x3 - 3.0 A 0x4 - 3.5 A 0x5 - 4.0 A 0x6 - Reserved - do not use. 0x7 - Reserved - do not use.
2:0	BUCK1_SLEW_RA TE[2:0]	R/W	0x2	Sets the output voltage slew rate for the Buck1 regulator (rising and falling edges): 0x0 - Reserved - do not use. 0x1 - Reserved - do not use. 0x2 - 10 mV/µs 0x3 - 7.5 mV/µs 0x4 - 3.8 mV/µs 0x5 - 1.9 mV/µs 0x6 - 0.94 mV/µs 0x7 - 0.47 mV/µs

7.6.1.7 BUCK0_VOUT

BUCK0_VOUT is shown in 表 7-21, Address: 0x06

表 7-20. BUCK0_VOUT Register

D7	D6	D5	D4	D3	D2	D1	D0
			BUCK0_\	/SET[7:0]			

表 7-21. BUCK0 VOUT Register Field Descriptions

Bits	Field	Type	Default	Description
7:0	BUCK0_VSET[7:0]	R/W	0x6B	Sets the output voltage of the Buck0 regulator: Reserved; do not use. 0x00 0x13 0.7 V - 0.73 V, 10 mV steps 0x14 - 0.7V 0x17 - 0.73 V 0.73 V - 1.4 V, 5 mV steps 0x18 - 0.735 V 0x9D - 1.4 V 1.4 V - 3.36 V, 20 mV steps 0x9E - 1.42 V
				0xFF - 3.36 V

7.6.1.8 BUCK1_VOUT

BUCK1_VOUT is shown in 表 7-23, Address: 0x07

表 7-22. BUCK1_VOUT Register

D7 D6	5 D5 D4	D3 D2	D1 D0
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BUCK1 VSET[7:0]

表 7-23. BUCK1_VOUT Register Field Descriptions

Bits	Field	Туре	Default	Description
7:0	BUCK1_VSET[7:0]	R/W	0x59	Sets the output voltage of the Buck0 regulator: Reserved; do not use. 0x00 0x13 0.7 V - 0.73 V, 10 mV steps 0x14 - 0.7V 0x17 - 0.73 V 0.73 V - 1.4 V, 5 mV steps 0x18 - 0.735 V 0x9D - 1.4 V 1.4 V - 3.36 V, 20 mV steps 0x9E - 1.42 V 0xFF - 3.36 V

7.6.1.9 LDO0_CTRL

LDO0_CTRL is shown in 表 7-25, Address: 0x08

表 7-24. LDO0_CTRL Register

D7	D6	D5	D4	D3	D2	D1	D0
					LDOG BDIC E	LDO0 EN PIN	IDO0 EN
	K	eserved - do not us		N N	LDO0_EN_PIN _CTRL	LDO0_EN	

表 7-25. LDO0_CTRL Register Field Descriptions

Bits	Field	Type	Default	Description
7:3	Reserved - do not use	R/W	0 0000	
2	LD00_RDIS_EN R/W 1		1	Enable output discharge resistor (R _{DIS_LDOx}) when the LDO0 is disabled: 0 - Discharge resistor is disabled. 1 - Discharge resistor is enabled.
1	LDO0_EN_PIN _CTRL	R/W	1	Enable control for the LDO0: 0 - only the LDO0_EN bit controls the LDO0. 1 - LDO0_EN bit and the EN pin control the LDO0.
0	LDO0_EN	R/W	1	Enable the LDO0 regulator: 0 - LDO0 regulator is disabled. 1 - LDO0 regulator is enabled.

7.6.1.10 LDO1_CTRL

LDO1_CTRL is shown in 表 7-27, Address: 0x09

表 7-26. LDO1_CTRL Register



表 7-27. LDO1_CTRL Register Field Descriptions

Bits	Field	Type	Default	Description
7:3	Reserved - do not use	R/W	0 0000	
2	LDO1_RDIS_EN	R/W		Enable output discharge resistor (R _{DIS_LDOx}) when the LDO1 is disabled: 0 - Discharge resistor is disabled. 1 - Discharge resistor is enabled.



表 7-27. LDO1_CTRL Register Field Descriptions (continued)

Bits	Field	Type	Default	Description	
1	LDO1_EN_PIN _CTRL	R/W	1	Enable control for the LDO1: 0 - only the LDO1_EN bit controls the LDO1. 1 - LDO1_EN bit <i>and</i> the EN pin control the LDO1.	
0	LDO1_EN	R/W	1	Enable the LDO1 regulator: 0 - LDO1 regulator is disabled. 1 - LDO1 regulator is enabled.	

7.6.1.11 LDO0_VOUT

LDO0_VOUT is shown in 表 7-29, Address: 0x0A

表 7-28. LDO0_VOUT Register

וט	D6	טט	D4	טט	D2	וט	D0
R	Reserved - do not u	se			LDO0_VSET[4:0]]	

表 7-29. LDO0_VOUT Register Field Descriptions

Bits	Field	Туре	Default	Description
7:5	Reserved - do not use	R/W	000	
4:0	LDO0_VSET[4:0]	R/W	0x19	Sets the output voltage of the LDO0 regulator: 0.8 V - 3.3 V, 100 mV steps 0x00 - 0.8V 0x19 - 3.3 V Reserved; do not use. 0x1A 0x1F

7.6.1.12 LDO1_VOUT

LDO1_VOUT is shown in 表 7-31, Address: 0x0B

表 7-30. LDO1_VOUT Register

D1	Во	Б3	D-1	В	DZ.	Di	Во
R	eserved - do not u	se			LDO1_VSET[4:0)]	

表 7-31. LDO1_VOUT Register Field Descriptions

Bits	Field	Туре	Default	Description
7:5	Reserved - do not use	R/W	000	
4:0	LDO1_VSET[4:0]	R/W	0x19	Sets the output voltage of the LDO1 regulator: 0.8 V - 3.3 V, 100 mV steps 0x00 - 0.8V 0x19 - 3.3 V Reserved; do not use. 0x1A 0x1F

7.6.1.13 BUCK0_DELAY

BUCK0_DELAY is shown in 表 7-33, Address: 0x0C

表 7-32. BUCK0_DELAY Register

D7	D6	D5	D4	D3	D2	D1	D0
	BUCK0_SHUTD(DWN_DELAY[3:0]			BUCK0_START	UP_DELAY[3:0]	

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表 7-33. BUCK0_DELAY Register Field Descriptions

				, <u> </u>
Bits	Field	Туре	Default	Description
7:4	BUCK0_ SHUTDOWN_ DELAY[3:0]	R/W	0x2	Shutdown delay of the Buck0 from the EN signal's falling edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.)
3:0	BUCK0_ STARTUP_ DELAY[3:0]	R/W	0x3	Startup delay of the Buck0 from the EN signal's rising edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.)

7.6.1.14 BUCK1_DELAY

BUCK1_DELAY is shown in 表 7-35, Address: 0x0D

表 7-34. BUCK1_DELAY Register

D7	D6	D5	D4	D3	D2	D1	D0
BUCK1_SHUTDOWN_DELAY[3:0]					BUCK1_START	UP_DELAY[3:0]	

表 7-35. BUCK1_DELAY Register Field Descriptions

Bits	Field	Type	Default	Description
7:4	BUCK1_ SHUTDOWN_ DELAY[3:0]	R/W	0x2	Shutdown delay of the Buck1 from the EN signal's falling edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.)
3:0	BUCK1_ STARTUP_ DELAY[3:0]	R/W	0x4	Startup delay of the Buck1 from the EN signal's rising edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.)

7.6.1.15 LDO0_DELAY

LDO0_DELAY is shown in 表 7-37, Address: 0x0E

表 7-36. LDO0_DELAY Register

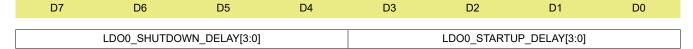


表 7-37. LDO0_DELAY Register Field Descriptions

Bits	Field	Type	Default	Description
7:4	LDO0_ SHUTDOWN_ DELAY[3:0]	R/W	0x0	Shutdown delay of the LDO0 from the EN signal's falling edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.)
3:0	LDO0_ STARTUP_ DELAY[3:0]	R/W	0x7	Startup delay of the LDO0 from the EN signal's rising edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.)

7.6.1.16 LDO1_DELAY

LDO1_DELAY is shown in 表 7-39, Address: 0x0F



表 7-38. LDO1_DELAY Register

D7	D6	D5	D4	D3	D2	D1	D0
	LDO1 SHUTDO	OWN DELAY[3:0]			LDO1 STARTI	JP DFI AY[3:0]	

表 7-39. LDO1_DELAY Register Field Descriptions

Bits	Field	Type	Default	Description
7:4	LDO1_ SHUTDOWN_ DELAY[3:0]	R/W	0x2	Shutdown delay of the LDO1 from the EN signal's falling edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.)
3:0	LDO1_ STARTUP_ DELAY[3:0]	R/W	0x5	Startup delay of the LDO1 from the EN signal's rising edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.)

7.6.1.17 GPO_DELAY

GPO_DELAY is shown in 表 7-41, Address: 0x10

表 7-40. GPO_DELAY Register

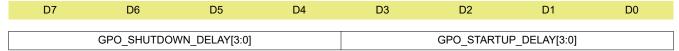


表 7-41. GPO_DELAY Register Field Descriptions

Bits	Field	Type	Default	Description	
7:4	GPO_ SHUTDOWN_ DELAY[3:0]	R/W	0x0	Delay for the GPO falling edge from the EN signal's falling edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register) 0xF - 7.5 ms (15 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register)	
3:0	GPO_ STARTUP_ DELAY[3:0]	R/W	0x7	Delay for the GPO rising edge from the EN signal's rising edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.)	

7.6.1.18 GPO2_DELAY

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GPO2_DELAY is shown in 表 7-43, Address: 0x11

表 7-42. GPO2_DELAY Register

D7	D6	D5	D4	D3	D2	D1	D0
	GPO2_SHUTDO	DWN_DELAY[3:0]			GPO2_START	JP_DELAY[3:0]	

表 7-43. GPO2_DELAY Register Field Descriptions

Bits	Field	Type	Default	Description
7:4	GPO2_ SHUTDOWN_ DELAY[3:0]	R/W	0x0	Delay for the GPO2 falling edge from the EN signal's falling edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if SHUTDOWN_DELAY_SEL=1 in the CONFIG register.)

表 7-43. GPO2_DELAY Register Field Descriptions (continued)

Bits	Field	Type	Default	Description
3:0	GPO2_ STARTUP_ DELAY[3:0]	R/W	0xA	Delay for the GPO2 rising edge from the EN signal's rising edge: 0x0 - 0 ms 0x1 - 0.5 ms (1 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.) 0xF - 7.5 ms (15 ms if STARTUP_DELAY_SEL=1 in the CONFIG register.)

7.6.1.19 GPO_CTRL

GPO_CTRL is shown in 表 7-45, Address: 0x12

表 7-44. GPO_CTRL Register

D7	D6	D5	D4	D3	D2	D1	D0
Reserved - do not use	GPO2_OD	GPO2_EN_PIN _CTRL	GPO2_EN	Reserved - do not use	GPO_OD	GPO_EN_PIN_ CTRL	GPO_EN

表 7-45. GPO_CTRL Register Field Descriptions

Bits	Field	Type	Default	Description
7	Reserved - do not use	R	0	
6	GP02_OD	R/W	1	GPO2 signal type when configured as the General Purpose Output (CLKIN pin): 0 - Push-pull output (VANA level) 1 - Open-drain output
5	GPO2_EN_PIN_CT RL	R/W	1	Control for the GPO2: 0 - Only the GPO2_EN bit controls the GPO2 1 - GPO2_EN bit and the EN pin control the GPO2.
4	GPO2_EN	R/W	1	Output level of the GPO2 signal (when configured as the General Purpose Output): 0 - Logic low level 1 - Logic high level
3	Reserved - do not use	R	0	
2	GPO_OD	R/W	1	GPO signal type: 0 - Push-pull output (VANA level) 1 - Open-drain output
1	GPO_EN_PIN_CTR L	R/W	1	Control for the GPO: 0 - Only the GPO_EN bit controls the GPO 1 - GPO_EN bit and the EN pin control the GPO.
0	GPO_EN	R/W	1	Output level of the GPO signal: 0 - Logic low level 1 - Logic high level

7.6.1.20 CONFIG

CONFIG is shown in 表 7-47, Address: 0x13

表 7-46. CONFIG Register

D7	D6	D5	D4	D3	D2	D1	D0
Reserved - do not use	STARTUP_DEL AY_SEL	SHUTDOWN_D ELAY_SEL	CLKIN_PIN_SE L	CLKIN_PD	EN2_PD	TDIE_WARN_ LEVEL	EN_SPREAD _SPEC

表 7-47. CONFIG Register Field Descriptions

Bits	Field	Type	Default	Description
7	Reserved - do not use	R/W	0	
6	STARTUP_DELAY_ SEL	R/W	0	Startup delay range from the EN signals: 0 - 0 ms - 7.5 ms with 0.5 ms steps 1 - 0 ms - 15 ms with 1 ms steps



表 7-47. CONFIG Register Field Descriptions (continued)

Bits	Field	Type	Default	Description
5	SHUTDOWN_DELA Y_SEL	R/W	0	Shutdown delay range from the EN signals: 0 - 0 ms - 7.5 ms with 0.5 ms steps 1 - 0 ms - 15 ms with 1 ms steps
4	CLKIN_PIN_SEL	R/W	0	CLKIN pin function: 0 - GPO2 1 - CLKIN
3	CLKIN_PD	R/W	0	Selects the pull down resistor on the CLKIN input pin (valid also when selected as GPO2): 0 - Pull-down resistor is disabled. 1 - Pull-down resistor is enabled.
2	EN_PD	R/W	1	Selects the pull down resistor on the EN input pin. 0 - Pull-down resistor is disabled. 1 - Pull-down resistor is enabled.
1	TDIE_WARN_ LEVEL	R/W	1	Thermal warning threshold level: 0 - 125°C 1 - 137°C
0	EN_SPREAD _SPEC	R/W	0	Enable spread spectrum feature: 0 - Disabled 1 - Enabled

7.6.1.21 PLL_CTRL

PLL_CTRL is shown in 表 7-49, Address: 0x14

表 7-48. PLL_CTRL Register

UI	DO	Do	D4	DS	DZ	וט	DU
Reserved - do not use	EN_PLL	Reserved - do not use		E	XT_CLK_FREQ[4	:0]	

表 7-49. PLL_CTRL Register Field Descriptions

Bits	Field	Type	Default	Description
7	Reserved - do not use	R/W	0	
6	EN_PLL	R/W	0	Selection of the external clock and PLL operation: 0 - Forced to the internal RC oscillator. The PLL is disabled. 1 - PLL is enabled in the STANDBY and ACTIVE modes. Automatic external clock use when available, and interrupt is generated if the external clock appears or disappears.
5	Reserved - do not use	R/W	0	This bit must be set to ""0 ."
4:0	EXT_CLK_FREQ[4: 0]	R/W	0x1	Frequency of the external clock (CLKIN): 0x00 - 1 MHz 0x01 - 2 MHz 0x02 - 3 MHz 0x16 - 23 MHz 0x17 - 24 MHz 0x180x1F - Reserved - do not use See electrical specification for the input clock frequency tolerance.

7.6.1.22 PGOOD_CTRL_1

PGOOD_CTRL_1 is shown in 表 7-51, Address: 0x15

表 7-50. PGOOD_CTRL_1 Register

D7 D6 D5	D4 D3	D2 [D1 D0
----------	-------	------	-------

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PGOOD_POL	PGOOD_OD	PGOOD_	PGOOD_	EN_PGOOD_L	EN_PGOOD_L	EN_PGOOD_B	EN_PGOOD_B
_		WINDOW_LDO	WINDOW_BUC	DO1	DO0	UCK1	UCK0
			K				

表 7-51. PGOOD_CTRL_1 Register Field Descriptions

Bits	Field	Type	Default	Description
7	PGOOD_POL	R/W	0	PGOOD signal polarity: 0 - PGOOD signal high when the monitored outputs are valid. 1 - PGOOD signal low when the monitored outputs are valid.
6	PGOOD_OD	R/W	1	PGOOD signal type: 0 - Push-pull output (VANA level) 1 - Open-drain output
5	PGOOD_ WINDOW_LDO	R/W	1	LDO Output voltage monitoring method for the PGOOD signal: 0 - Only undervoltage monitoring 1 - Overvoltage and undervoltage monitoring
4	PGOOD_ WINDOW_BUCK	R/W	1	Buck Output voltage monitoring method for the PGOOD signal: 0 - Only undervoltage monitoring 1 - Overvoltage and undervoltage monitoring
3	EN_PGOOD_LDO1	R/W	0	PGOOD signal source control from LDO1: 0 - LDO1 is not monitored. 1 - LDO1 Power-Good threshold voltage is monitored.
2	EN_PGOOD_LDO0	R/W	0	PGOOD signal source control from theLDO0: 0 - LDO0 is not monitored. 1 - LDO0 Power-Good threshold voltage is monitored.
1	EN_PGOOD_BUCK 1	R/W	1	PGOOD signal source control from the Buck1: 0 - Buck1 is not monitored. 1 - Buck1 Power-Good threshold voltage is monitored.
0	EN_PGOOD_BUCK 0	R/W	1	PGOOD signal source control from the Buck0: 0 - Buck0 is not monitored. 1 - Buck0 Power-Good threshold voltage is monitored.

7.6.1.23 PGOOD_CTRL_2

PGOOD_CTRL_2 is shown in 表 7-53, Address: 0x16

表 7-52. PGOOD_CTRL_2 Register

D1	Do	D3	D4	D3	DZ	וט	Ъ
	Re	eserved - do not us	se		EN_PGOOD_T WARN	PG_FAULT_GA TES_PGOOD	PGOOD_MOD E

表 7-53. PGOOD_CTRL_2 Register Field Descriptions

Bits	Field	Type	Default	Description
7:3	Reserved - do not use	R/W	0 0000	
2	EN_PGOOD_TWA RN	R/W	1	Thermal warning control for the PGOOD signal: 0 - Thermal warning is not monitored. 1 - PGOOD inactive if the thermal warning flag is active.
1	PG_FAULT_GATES _PGOOD	R/W	0	Type of operation for the PGOOD signal: 0 - Indicates live status of monitored voltage outputs. 1 - Indicates status of the PG_FAULT register, inactive when at least one PG_FAULT_x bit is inactive.
0	PGOOD_MODE	R/W	0	Operating mode for the PGOOD signal: 0 - Gated mode 1 - Continuous mode

7.6.1.24 PG_FAULT

PG_FAULT is shown in 表 7-55, Address: 0x17



表 7-54. PG_FAULT Register

		_	-	•			
D7	D6	D5	D4	D3	D2	D1	D0
	Reserved	- do not use		PG_FAULT_LD	PG_FAULT_LD	PG_FAULT_BU	PG_FAULT_BU
				01	00	CK1	CK0

表 7-55. PG_FAULT Register Field Descriptions

Bits	Field	Type	Default	Description
7:4	Reserved - do not use	R/W	0000	2000 Pilot
3	PG_FAULT_LDO1	R/W	0	Source for the PGOOD inactive signal: 0 - LDO1 has not set the PGOOD signal inactive. 1 - LDO1 is selected for the PGOOD signal and it has set the PGOOD signal inactive. This bit can be cleared by writing '1' to this bit when the LDO1 output is valid.
2	PG_FAULT_LDO0	R/W	0	Source for PGOOD inactive signal: 0 - LDO0 has not set the PGOOD signal inactive. 1 - LDO0 is selected for the PGOOD signal and it has set the PGOOD signal inactive. This bit can be cleared by writing '1' to this bit when the LDO0 output is valid.
1	PG_FAULT_BUCK1	R/W	0	Source for PGOOD inactive signal: 0 - Buck1 has not set PGOOD signal inactive. 1 - Buck1 is selected for the PGOOD signal and it has set the PGOOD signal inactive. This bit can be cleared by writing '1' to this bit when the Buck1 output is valid.
0	PG_FAULT_BUCK0	R/W	0	Source for PGOOD inactive signal: 0 - Buck0 has not set PGOOD signal inactive. 1 - Buck0 is selected for the PGOOD signal and it has set the PGOOD signal inactive. This bit can be cleared by writing '1' to this bit when the Buck0 output is valid.

7.6.1.25 RESET

RESET is shown in 表 7-57, Address: 0x18

表 7-56. RESET Register

		R	eserved - do not u	ise			SW RESET
D7	D6	D5	D4	D3	D2	D1	D0

表 7-57. RESET Register Field Descriptions

	24 * **********************************								
Bits	Field	Type	Default	Description					
7:1	Reserved - do not use	R/W	000 0000						
0	SW_RESET	R/W	0	Software commanded reset. When written to 1, the registers will be reset to the default values, the OTP memory is read, and the I ² C interface is reset. The bit is automatically cleared.					

7.6.1.26 INT_TOP_1

INT_TOP_1 is shown in 表 7-59, Address: 0x19

表 7-58. INT_TOP_1 Register

	D/	D6	D5	D4	D3	D2	D1	D0
_								
	PGOOD_INT	LDO_INT	BUCK_INT	SYNC_CLK_IN	TDIE_SD_INT	TDIE_WARN_I	OVP_INT	I_MEAS_INT
				T		NT		

表 7-59. INT_TOP_1 Register Field Descriptions

Bits	Field	Туре	Default	Description	
7	PGOOD_INT	R/W	0	Latched status bit indicating that the PGOOD pin has changed from active to inactive. Write 1 to clear interrupt.	

表 7-59. INT_TOP_1 Register Field Descriptions (continued)

Bits	Field	Type	Default	Description
6	LDO_INT	R	0	Interrupt indicating that the LDO1 and LDO0 have a pending interrupt. The reason for the interrupt is indicated in the INT_LDO register. This bit is cleared automatically when the INT_LDO register is cleared to 0x00.
5	BUCK_INT	R	0	Interrupt indicating that the Buck1 and Buck0 have a pending interrupt. The reason for the interrupt is indicated in the INT_BUCK register. This bit is cleared automatically when INT_BUCK register is cleared to 0x00.
4	SYNC_CLK_INT	R/W	0	Latched status bit indicating that the external clock has appeared or disappeared. Write 1 to clear interrupt.
3	TDIE_SD_INT	R/W	0	Latched status bit indicating that the die junction temperature has exceeded the thermal shutdown level. The regulators have been disabled if they were enabled and the GPO and GPO2 signals are driven low. The regulators cannot be enabled if this bit is active. The actual status of the thermal shutdown is indicated by the TDIE_SD_STAT bit in the TOP_STAT register. Write 1 to clear interrupt.
2	TDIE_WARN_INT	R/W	0	Latched status bit indicating that the die junction temperature has exceeded the thermal warning level. The actual status of the thermal warning is indicated by the TDIE_WARN_STAT bit in the TOP_STAT register. Write 1 to clear interrupt.
1	OVP_INT	R/W	0	Latched status bit indicating that the input voltage has exceeded the over-voltage detection level. The regulators have been disabled if they were enabled and the GPO and GPO2 signals are driven low. The actual status of the over-voltage is indicated by the OVP_STAT bit in the TOP_STAT register. Write 1 to clear interrupt.
0	I_MEAS_INT	R/W	0	Latched status bit indicating that the load current measurement result is available in the I_LOAD_1 and I_LOAD_2 registers. Write 1 to clear interrupt.

7.6.1.27 INT_TOP_2

INT_TOP_2 is shown in 表 7-61, Address: 0x1A

表 7-60. INT_TOP_2 Register

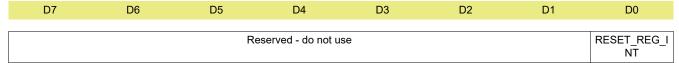


表 7-61. INT_TOP_2 Register Field Descriptions

Bits	Field	Type	Default	Description
7:1	Reserved - do not use	R/W	000 0000	
0	RESET_REG_INT	R/W	0	Latched status bit indicating that either VANA supply voltage has been below the undervoltage threshold level or the host has requested a reset using the SW_RESET bit in RESET register. The regulators have been disabled, the registers are reset to the default values, and the normal startup procedure is done. Write 1 to clear interrupt.

7.6.1.28 INT_BUCK

INT_BUCK is shown in 表 7-63, Address: 0x1B

表 7-62. INT_BUCK Register

D7	D6	D5	D4	D3	D2	D1	D0
Reserved - do not use	BUCK1_PG _INT	BUCK1_SC _INT	BUCK1_ILIM _INT	Reserved - do not use	BUCK0_PG _INT	BUCK0_SC _INT	BUCK0_ILIM _INT

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表 7-63. INT_BUCK Register Field Descriptions

Bits	Field	Type	Default	Description
7	Reserved - do not use	R/W	0	
6	BUCK1_PG_INT	R/W	0	Latched status bit indicating that Buck1 Power-Good event has been detected. Write 1 to clear.
5	BUCK1_SC_INT	R/W	0	Latched status bit indicating that the Buck1 output voltage has been over 1 ms below the short-circuit threshold level. Write 1 to clear.
4	BUCK1_ILIM_INT	R/W	0	Latched status bit indicating that the Buck1 output current limit has been active. Write 1 to clear.
3	Reserved - do not use	R/W	0	
2	BUCK0_PG_INT	R/W	0	Latched status bit indicating that the Buck0 Power-Good event has been detected. Write 1 to clear.
1	BUCK0_SC_INT	R/W	0	Latched status bit indicating that the Buck0 output voltage has been over 1 ms below the short-circuit threshold level. Write 1 to clear.
0	BUCK0_ILIM_INT	R/W	0	Latched status bit indicating that the Buck0 output current limit has been active. Write 1 to clear.

7.6.1.29 INT_LDO

INT_LDO is shown in 表 7-65, Address: 0x1C

表 7-64. INT_LDO Register

D7	D6	D5	D4	D3	D2	D1	D0
Reserved - do not use	LDO1_PG _INT	LDO1_SC _INT	LDO1_ILIM _INT	Reserved - do not use	LDO0_PG _INT	LDO0_SC _INT	LDO0_ILIM _INT

表 7-65. INT_LDO Register Field Descriptions

X 7 00. INT_EDO Register Field Descriptions								
Bits	Field	Type	Default	Description				
7	Reserved - do not use	R/W	0					
6	LDO1_PG_INT	R/W	0	Latched status bit indicating that the LDO1 Power-Good event has been detected. Write 1 to clear.				
5	LDO1_SC_INT	R/W	0	Latched status bit indicating that the LDO1 output voltage has been over 1 ms below the short-circuit threshold level. Write 1 to clear.				
4	LDO1_ILIM_INT	R/W	0	Latched status bit indicating that the LDO1 output current limit has been active. Write 1 to clear.				
3	Reserved - do not use	R/W	0					
2	LDO0_PG_INT	R/W	0	Latched status bit indicating that the LDO0 Power-Good event has been detected. Write 1 to clear.				
1	LDO0_SC_INT	R/W	0	Latched status bit indicating that the LDO0 output voltage has been over 1 ms below the short-circuit threshold level. Write 1 to clear.				
0	LDO0_ILIM_INT	R/W	0	Latched status bit indicating that the LDO0 output current limit has been active. Write 1 to clear.				

7.6.1.30 TOP_STAT

TOP_STAT is shown in 表 7-67, Address: 0x1D

表 7-66. TOP_STAT Register

D7	D6	D5	D4	D3	D2	D1	D0



PGOOD_STAT	Reserved - do not use	SYNC_CLK	TDIE_SD	TDIE_WARN	OVP_STAT	Reserved - do
		_STAT	_STAT	_STAT		not use

表 7-67. TOP_STAT Register Field Descriptions

Bits	Field	Type	Default	Description
7	PGOOD_STAT	R	0	Status bit indicating the status of the PGOOD pin: 0 - PGOOD pin is inactive. 1 - PGOOD pin is active.
6:5	Reserved - do not use	R	00	
4	SYNC_CLK_STAT	R	0	Status bit indicating the status of the external clock (CLKIN): 0 - External clock frequency is valid. 1 - External clock frequency is not valid.
3	TDIE_SD_STAT	R	0	Status bit indicating the status of the thermal shutdown: 0 - Die temperature below the thermal shutdown level. 1 - Die temperature above the thermal shutdown level.
2	TDIE_WARN _STAT	R	0	Status bit indicating the status of thermal warning: 0 - Die temperature below the thermal warning level. 1 - Die temperature above the thermal warning level.
1	OVP_STAT	R	0	Status bit indicating the status of the input overvoltage monitoring: 0 - Input voltage is below overvoltage threshold level. 1 - Input voltage above overvoltage threshold level.
0	Reserved - do not use	R	0	

7.6.1.31 BUCK_STAT

BUCK_STAT is shown in 表 7-69, Address: 0x1E

表 7-68. BUCK_STAT Register

D1	Do	D3	D4	Ъ3	DZ	Di	В
BUCK1_STAT	BUCK1_PG _STAT	Reserved - do not use	BUCK1_ILIM _STAT	BUCK0_STAT	BUCK0_PG _STAT	Reserved - do not use	BUCK0_ILIM _STAT

表 7-69. BUCK_STAT Register Field Descriptions

Bits	Field	Туре	Default	Description
7	BUCK1_STAT	R	0	Status bit indicating the enable and disable status of the Buck1: 0 - Buck1 regulator is disabled. 1 - Buck1 regulator is enabled.
6	BUCK1_PG_STAT	R	0	Status bit indicating the Buck1 output voltage validity (raw status): 0 - Buck1 output voltage is valid. 1 - Buck1 output voltage is invalid.
5	Reserved - do not use	R	0	
4	BUCK1_ILIM _STAT	R	0	Status bit indicating the Buck1 current limit status (raw status): 0 - Buck1 output current is below the current limit level. 1 - Buck1 output current limit is active.
3	BUCK0_STAT	R	0	Status bit indicating the enable and disable status of the Buck0: 0 - Buck0 regulator is disabled. 1 - Buck0 regulator is enabled.
2	BUCK0_PG_STAT	R	0	Status bit indicating the Buck0 output voltage validity (raw status): 0 - Buck0 output voltage is valid. 1 - Buck0 output voltage is invalid.
1	Reserved - do not use	R	0	



表 7-69. BUCK_STAT Register Field Descriptions (continued)

Bits	Field	Type	Default	Description
0	BUCK0_ILIM _STAT	R	0	Status bit indicating the Buck0 current limit status (raw status): 0 - Buck0 output current is below the current limit level. 1 - Buck0 output current limit is active.

7.6.1.32 LDO_STAT

LDO_STAT is shown in 表 7-71, Address: 0x1F

表 7-70. LDO_STAT Register

D7	D6	D5	D4	D3	D2	D1	D0
LDO1_STAT	LDO1_PG STAT	Reserved - do	LDO1_ILIM STAT	LDO0_STAT	LDO0_PG STAT	Reserved - do	LDO0_ILIM STAT

表 7-71. LDO_STAT Register Field Descriptions

Bits	Field	Type	Default	Description
7	LDO1_STAT	R	0	Status bit indicating the enable and disable status of the LDO1: 0 - LDO1 regulator is disabled. 1 - LDO1 regulator is enabled.
6	LDO1_PG_STAT	R	0	Status bit indicating the LDO1 output voltage validity (raw status): 0 - LDO1 output voltage is valid. 1 - LDO1 output voltage is invalid.
5	Reserved - do not use	R	0	
4	LDO1_ILIM _STAT	R	0	Status bit indicating the LDO1 current limit status (raw status): 0 - LDO1 output current is below the current limit level. 1 - LDO1 output current limit is active.
3	LDO0_STAT	R	0	Status bit indicating the enable and disable status of the LDO0: 0 - LDO0 regulator is disabled. 1 - LDO0 regulator is enabled.
2	LDO0_PG_STAT	R	0	Status bit indicating the LDO0 output voltage validity (raw status): 0 - LDO0 output voltage is valid. 1 - LDO0 output voltage is invalid.
1	Reserved - do not use	R	0	
0	LDO0_ILIM _STAT	R	0	Status bit indicating the LDO0 current limit status (raw status): 0 - LDO0 output current is below the current limit level. 1 - LDO0 output current limit is active.

7.6.1.33 TOP_MASK_1

TOP_MASK_1 is shown in 表 7-73, Address: 0x20

表 7-72. TOP_MASK_1 Register

D7	D6	D5	D4	D3	D2	D1	D0
PGOOD_INT_ MASK	Reserved -	do not use	SYNC_CLK _MASK	Reserved - do not use	TDIE_WARN _MASK	Reserved - do not use	I_LOAD_ READY_MASK

表 7-73. TOP_MASK_1 Register Field Descriptions

Bits	Field	Type	Default	Description						
7	PGOOD_INT _MASK	R/W	1	Masking for Power-Good interrupt (PGOOD_INT in INT_TOP_1 register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the PGOOD_STAT status bit in the TOP_STAT register.						
6:5	Reserved - do not use	R/W	00							

表 7-73. TOP_MASK_1 Register Field Descriptions (continued)

D ::		-		_ · _ ·
Bits	Field	Type	Default	Description
4	SYNC_CLK _MASK	R/W	1	Masking for the external clock detection interrupt (SYNC_CLK_INT in INT_TOP_1 register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the SYNC_CLK_STAT status bit in the TOP_STAT register.
3	Reserved - do not use	R/W	0	
2	TDIE_WARN _MASK	R/W	0	Masking for the thermal warning interrupt (TDIE_WARN_INT in INT_TOP_1 register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the TDIE_WARN_STAT status bit in the TOP_STAT register.
1	Reserved - do not use	R/W	0	
0	I_MEAS _MASK	R/W	0	Masking for the load current measurement ready interrupt (MEAS_INT in INT_TOP_1 register): 0 - Interrupt is generated. 1 - Interrupt is not generated.

7.6.1.34 TOP_MASK_2

TOP_MASK_2 is shown in 表 7-75, Address: 0x21

表 7-74. TOP_MASK_2 Register



表 7-75. TOP_MASK_2 Register Field Descriptions

Bits	Field	Type	Default	Description
7:1	Reserved - do not use	R/W	000 0000	
0	RESET_REG _MASK	R/W	1	Masking for register reset interrupt (RESET_REG_INT in INT_TOP_2 register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This change of this bit by I ² C writing has no effect because it will be read from OTP memory during reset.

7.6.1.35 BUCK_MASK

BUCK_MASK is shown in 表 7-77, Address: 0x22

表 7-76. BUCK_MASK Register

D7	D6	D5	D4	D3	D2	D1	D0
BUCK1_PGF	BUCK1_PGR	Reserved - do	BUCK1_ILIM	BUCK0_PGF	BUCK0_PGR	Reserved - do	BUCK0_ILIM
_MASK	_MASK	not use	_MASK	_MASK	_MASK	not use	_MASK

表 7-77. BUCK_MASK Register Field Descriptions

Bits	Field	Type	Default	Description		
7	BUCK1_PGF_MAS	R/W	1	Masking of the Power Good invalid detection for the Buck1 power good interrupt		
	K			(BUCK1_PG_INT in INT_BUCK register):		
				0 - Interrupt is generated.		
				1 - Interrupt is not generated.		
				This bit does not affect the BUCK1_PG_STAT status bit in the BUCK_STAT register.		



表 7-77. BUCK_MASK Register Field Descriptions (continued)

Bits	Field	Type	Default	Description		
6	BUCK1_PGR_MAS K	R/W	1	Masking of the Power Good valid detection for the Buck1 Power Good interrupt (BUCK1_PG_INT in INT_BUCK register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the BUCK1_PG_STAT status bit in the BUCK_STAT register.		
5	Reserved - do not use	R	0			
4	BUCK1_ILIM _MASK	R/W	0	Masking for the Buck1 current limit detection interrupt (BUCK1_ILIM_INT in INT_BUCK register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the BUCK1_ILIM_STAT status bit in the BUCK_STAT register.		
3	BUCK0_PGF_MAS K	R/W	1	Masking of the Power Good invalid detection for the Buck0 power good interrupt (BUCK0_PG_INT in INT_BUCK register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect BUCK0_PG_STAT status bit in BUCK_STAT register.		
2	BUCK0_PGR_MAS K	R/W	1	Masking of the Power Good valid detection for the Buck0 power good interrupt (BUCK0_PG_INT in INT_BUCK register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the BUCK0_PG_STAT status bit in the BUCK_STAT register.		
1	Reserved - do not use	R	0			
0	BUCK0_ILIM _MASK	R/W	0	Masking for the Buck0 current limit detection interrupt (BUCK0_ILIM_INT in INT_BUCK register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the BUCK0_ILIM_STAT status bit in the BUCK_STAT register.		

7.6.1.36 LDO_MASK

LDO_MASK is shown in 表 7-79, Address: 0x23

表 7-78. LDO_MASK Register

D/	D6	D5	D4	D3	D2	ט1	DO
LDO1_PGF	LDO1_PGR	Reserved - do	LDO1_ILIM	LDO0_PGF	LDO0_PGR	Reserved - do	LDO0_ILIM
_MASK	_MASK	not use	_MASK	_MASK	_MASK	not use	_MASK

表 7-79. LDO_MASK Register Field Descriptions

Bits	Field	Type	Default	Description
7	LDO1_PGF_MASK	R/W	1	Masking of the Power Good invalid detection for the LDO1 power good interrupt (LDO1_PG_INT in INT_LDO register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the LDO1_PG_STAT status bit in the LDO_STAT register.
6	LDO1_PGR_MASK	R/W	1	Masking of the Power Good valid detection for the LDO1 power good interrupt (LDO1_PG_INT in INT_LDO register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the LDO1_PG_STAT status bit in the LDO_STAT register.
5	Reserved - do not use	R	0	
4	LDO1_ILIM _MASK	R/W	0	Masking for the LDO1 current limit detection interrupt (LDO1_ILIM_INT in INT_LDO register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the LDO1_ILIM_STAT status bit in the LDO_STAT register.

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表 7-79. LDO_MASK Register Field Descriptions (continued)

Bits	Field	Type	Default	Description
3	LDO0_PGF_MASK	R/W	1	Masking of the Power Good invalid detection for the LDO0 power good interrupt (LDO0_PG_INT in INT_LDO register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the LDO0_PG_STAT status bit in the LDO_STAT register.
2	LDO0_PGR_MASK	R/W	1	Masking of Power Good valid detection for the LDO0 power good interrupt (LDO0_PG_INT in INT_LDO register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the LDO0_PG_STAT status bit in the LDO_STAT register.
1	Reserved - do not use	R	0	
0	LDO0_ILIM _MASK	R/W		Masking for the LDO0 current limit detection interrupt (LDO0_ILIM_INT in INT_LDO register): 0 - Interrupt is generated. 1 - Interrupt is not generated. This bit does not affect the LDO0_ILIM_STAT status bit in the LDO_STAT register.

7.6.1.37 SEL_I_LOAD

SEL_I_LOAD is shown in 表 7-81, Address: 0x24



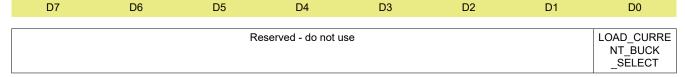


表 7-81. SEL_I_LOAD Register Field Descriptions

				
Bits	Field	Type	Default	Description
7:1	Reserved - do not use	R/W	000 0000	
0	LOAD_CURRENT_ BUCK_SELECT	R/W	0	Start the current measurement on the selected regulator: 0 - Buck0 1 - Buck1 The measurement is started when the register is written.

7.6.1.38 I_LOAD_2

I_LOAD_2 is shown in 表 7-83, Address: 0x25

表 7-82. I_LOAD_2 Register

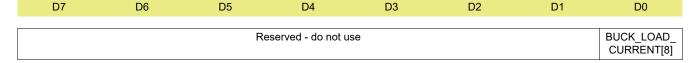


表 7-83. I_LOAD_2 Register Field Descriptions

Bits	Field	Type	Default	Description
7:1	Reserved - do not use	R	000 0000	
0	BUCK_LOAD_ CURRENT[8]	R	0	This register describes the MSB bit of the average load current on the selected regulator with a resolution of 20 mA per LSB and maximum 10.22-A current.



7.6.1.39 I_LOAD_1

I_LOAD_1 is shown in 表 7-85, Address: 0x26

表 7-84. I_LOAD_1 Register

D7	D6	D5	D4	D3	D2	D1	D0						
	BUCK_LOAD_CURRENT[7:0]												

表 7-85. I_LOAD_1 Register Field Descriptions

Bits	Field	Туре	Default	Description	
7:0	BUCK_LOAD_ CURRENT[7:0]	R		This register describes 8 LSB bits of the average load current on the selected regulator with a resolution of 20 mA per LSB and maximum 10.22-A current.	

Product Folder Links: LP87332D-Q1

Submit Document Feedback



8 Application and Implementation

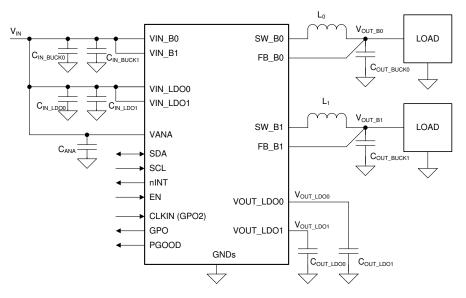
Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LP87332D-Q1 is a power management unit including two step-down regulators, two linear regulators, and two general-purpose digital output signals.

8.2 Typical Application



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图 8-1. LP87332D-Q1 Typical Application

8.2.1 Design Requirements

8.2.1.1 Inductor Selection

The inductors L_0 and L_1 are shown in the # 8.2. The inductance and DCR of the inductor affects the control loop of the buck regulator. TI recommends using inductors similar to those listed in # 8-1. Pay attention to the saturation current and temperature rise current of the inductor. Check that the saturation current is higher than the peak current limit and the temperature rise current is higher than the maximum expected rms output current. The minimum effective inductance to ensure good performance is 0.22 μH at maximum peak output current over the operating temperature range. DC resistance of the inductor must be less than 0.05 Ω for good efficiency at high-current conditions. The inductor AC loss also affects conversion efficiency. Higher Q factor at switching frequency usually gives better efficiency at light load to middle load. Shielded inductors are preferred, as they radiate less noise.

表 8-1. Recommended Inductors

MANUFACTURER	PART NUMBER	VALUE	DIMENSIONS L × W × H (mm)	RATED DC CURRENT I _{SAT} maximum (typical) / I _{TEMP} maximum (typical) (A)	DCR typical / maximum (mΩ)
ТОКО	DFE252012PD- R47M	0.47 µH (20%)	2.5 × 2 × 1.2	5.2 (-) / 4 (-) ⁽¹⁾	— / 27



表 8-1. Recommended Inductors (continued)

MANUFACTURER	PART NUMBER	VALUE	DIMENSIONS L × W × H (mm)	RATED DC CURRENT I _{SAT} maximum (typical) / I _{TEMP} maximum (typical) (A)	DCR typical / maximum (mΩ)
Tayo Yuden	MDMK2020TR47MM V	0.47 µH (20%)	2 × 2 ×1.2	4.2 (4.8) / 2.3 (2.45)	40 / 46

(1) Operating temperature range is up to 125°C including self temperature rise.

8.2.1.2 Buck Input Capacitor Selection

The input capacitors C_{IN_BUCK0} and C_{IN_BUCK1} are shown in the # 8.2. A ceramic input bypass capacitor of 10 μF is required for each phase of the regulator. Place the input capacitor as close as possible to the VIN_Bx pin and PGND_Bx pin of the device. A larger value or higher voltage rating improves the input voltage filtering. Use X7R type of capacitors, not Y5V or F. Also, the DC bias characteristics capacitors must be considered. The minimum effective input capacitance to ensure good performance is 1.9 μF per buck input at maximum input voltage including tolerances, ambient temperature range, and aging (assuming at least 22 μF of additional capacitance is common for all the power input pins on the system power rail). See # 8-2.

The input filter capacitor supplies current to the high-side FET switch in the first half of each cycle and reduces voltage ripple imposed on the input power source. The low ESR of the ceramic capacitor provides the best noise filtering of the input voltage spikes due to this rapidly changing current. Select an input filter capacitor with sufficient ripple current rating. In addition, ferrite can be used in front of the input capacitor to reduce the EMI.

表 8-2. Recommended Buck Input Capacitor (X7R Dielectric)

MANUFACTURER	PART NUMBER	VALUE	CASE SIZE	DIMENSIONS L × W × H (mm)	VOLTAGE RATING
Murata	GCM21BR71A106KE22	10 μF (10%)	0805	2 × 1.25 × 1.25	10 V

8.2.1.3 Buck Output Capacitor Selection

The output capacitor C_{OUT_BUCK0} and C_{OUT_BUCK1} are shown in #8.2. A ceramic local output capacitor of 22 µF is required per phase. Use ceramic capacitors, X7R type; do not use Y5V or F. DC bias voltage characteristics of ceramic capacitors must be considered. The output filter capacitor smooths out current flow from the inductor to the load, which helps maintain a steady output voltage during transient load changes and reduces output voltage ripple. These capacitors must be selected with sufficient capacitance and sufficiently low ESR and ESL to perform these functions. The minimum effective output capacitance to ensure good performance is 10 µF per phase, including the DC voltage rolloff, tolerances, aging, and temperature effects.

The output voltage ripple is caused by the charging and discharging of the output capacitor and due to its R_{ESR} . The R_{ESR} is frequency dependent (and temperature dependent); ensure the value used for selection process is at the switching frequency of the part. See $\frac{1}{8}$ 8-3.

POL capacitors can be used to improve load transient performance and to decrease the ripple voltage. A higher output capacitance improves the load step behavior, reduces the output voltage ripple, and decreases the PFM switching frequency. However, output capacitance higher than 150 μ F per phase is not necessarily of any benefit. The output capacitor may be the limiting factor in the output voltage ramp, see \dagger 6 for maximum output capacitance for different slew-rate settings. For large output capacitors, the output voltage might be slower than the programmed ramp rate at voltage transitions, because of the higher energy stored on the output capacitance. Also at start-up, the time required to charge the output capacitor to target value might be longer. At shutdown, the output voltage is discharged to a 0.6 V level using forced-PWM operation. This can increase the input voltage if the load current is small and the output capacitor is large compared to input capacitor. Below the 0.6 V level, the output capacitor is discharged by the internal discharge resistor, and with large capacitor more time is required to settle V_{OUT} down as a consequence of the increased time constant.

表 8-3. Recommended Buck Output Capacitors (X7R Dielectric)

MANUFACTURER	PART NUMBER	VALUE	CASE SIZE	DIMENSIONS L × W × H (mm)	VOLTAGE RATING	
Murata	GCM31CR71A226KE02	22 µF (10%)	1206	3.2 × 1.6 × 1.6	10 V	

8.2.1.4 LDO Input Capacitor Selection

The input capacitors C_{IN_LDO0} and C_{IN_LDO1} are shown in the $\frac{1}{8}$ 8-4. A ceramic input capacitor of 2.2 μF, 6.3 V is sufficient for most applications. Place the input capacitor as close as possible to the VIN_LDOx pin and AGND pin of the device. A larger value or higher voltage rating improves the input voltage filtering. Use X7R type of capacitors, not Y5V or F. DC bias characteristics of capacitors must be considered, the minimum effective input capacitance to ensure good performance is 0.6 μF per LDO input at maximum input voltage including tolerances, ambient temperature range, and aging. See $\frac{1}{8}$ 8-4.

表 8-4. Recommended LDO Input Capacitors (X7R Dielectric)

MANUFACTURER	FACTURER PART NUMBER		CASE SIZE	DIMENSIONS L × W × H (mm)	VOLTAGE RATING	
Murata	GCM188R70J225KE22	2.2 µF (10%)	0603	1.6 × 0.8 × 0.8	6.3 V	
Murata	GCM21BR71C475KA73	4.7 µF (10%)	0805	2 × 1.25 × 1.25	16 V	

8.2.1.5 LDO Output Capacitor Selection

The output capacitors C_{OUT_LDO0} and C_{OUT_LDO1} are shown in the \dagger 8.2. A ceramic output capacitor of minimum 1.0 μF is required. Place the output capacitor as close to the VOUT_LDOx pin and AGND pin of the device as possible. Use X7R type of capacitors, not Y5V or F. DC bias characteristics of capacitors must be considered, the minimum effective output capacitance to ensure good performance is 0.4 μF per LDO input at maximum input voltage including tolerances, ambient temperature range, and aging. See $\frac{1}{5}$ 8-5.

Note: the output capcitor requirements excludes any capacitance seen at the point of load and only refers to the capacitance seen close to the device. Additional capacitance placed near the load can be supported, but the end application system should be evaluated for stability and to ensure the sequencing requirements are met. The shutdown decay will be longer with higher output capcitance, which can also impact the startup time. Total output capacitance should be kept below $100 \ \mu F$.

The output capacitance must be smaller than the input capacitance to ensure the stability of the LDO. With a 1-µF output capacitor, TI recommends using at least a 2.2-µF input capacitor; with a 2.2-µF output capacitor at least 4.7-µF input capacitance.

The VANA input is used to supply analog and digital circuits in the device. See 表 8-6 for recommended components from for VANA input supply filtering.

表 8-5. Recommended LDO Output Capacitors (X7R Dielectric)

MANUFACTURER	PART NUMBER	VALUE	CASE SIZE	DIMENSIONS L × W × H (mm)	VOLTAGE RATING
Murata	GCM188R71C105KA64	1 μF (10%)	0603	1.6 × 0.8 × 0.8	16 V
Murata	GCM188R70J225KE22	2.2 µF (10%)	0603	1.6 × 0.8 × 0.8	6.3 V

表 8-6. Recommended Supply Filtering Components

MANUFACTURER	PART NUMBER	VALUE	CASE SIZE	DIMENSIONS L × W × H (mm)	VOLTAGE RATING	
Murata	GCM155R71C104KA55	100 nF (10%)	0402	1 × 0.5 × 0.5	16 V	
Murata	GCM188R71C104KA37	100 nF (10%)	0603	1.6 × 0.8 × 0.8	16 V	

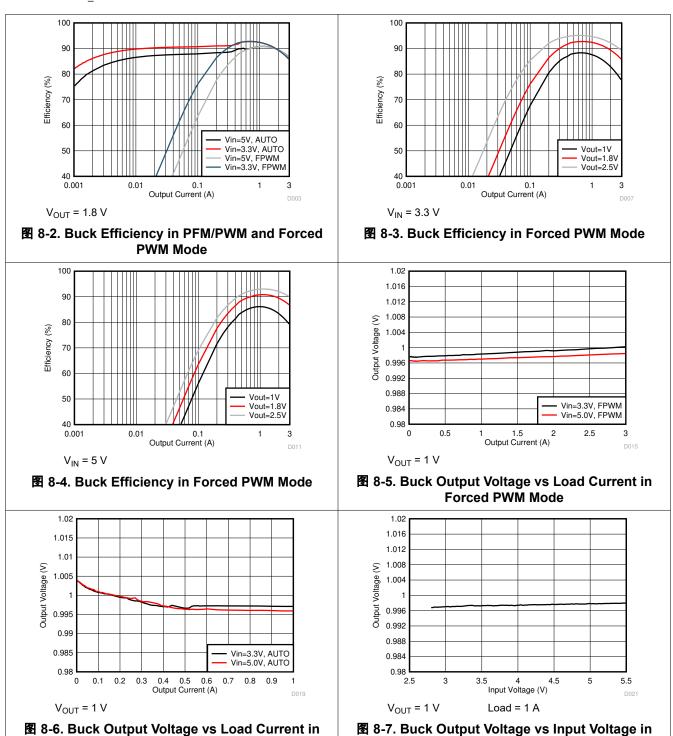
8.2.2 Detailed Design Procedure

The performance of the LP87332D-Q1 device depends greatly on the care taken in designing the printed circuit board (PCB). The use of low-inductance and low serial-resistance ceramic capacitors is strongly recommended, while proper grounding is crucial. Attention must be given to decoupling the power supplies. Decoupling capacitors must be connected close to the device and between the power and ground pins to support high peak currents being drawn from system power rail during turnon of the switching MOSFETs. Keep input and output traces as short as possible, because trace inductance, resistance, and capacitance can become performance limiting items. The separate buck regulator power pins VIN_Bx are not connected together internally. Connect the VIN_Bx power connections together outside the package using power plane construction.



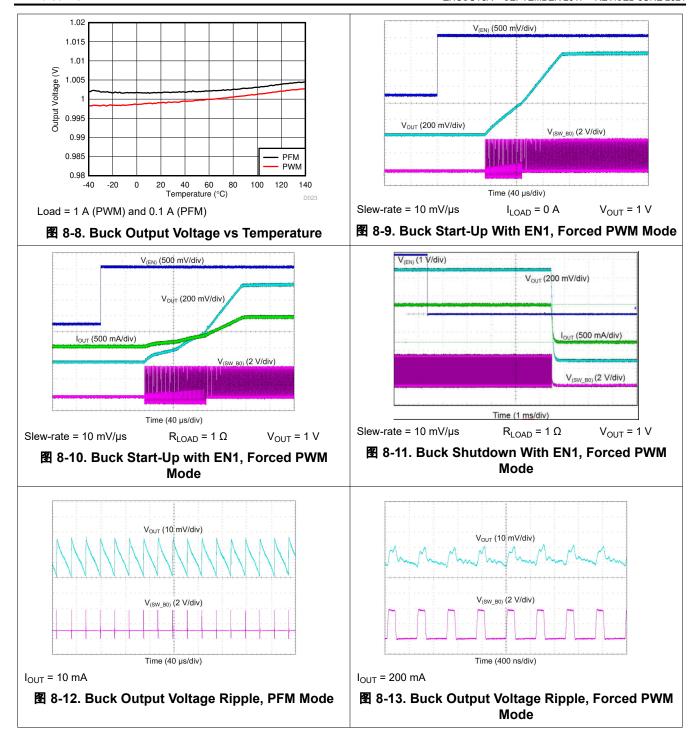
8.2.3 Application Curves

Measurements are done using typical application set up with connections shown in 88-1. Graphs may not reflect the OTP default settings. Unless otherwise specified: $V_{(VIN_Bx)} = V_{(VIN_LDOx)} = V_{(VANA)} = 3.7 \text{ V}$, $V_{OUT_Bx} = 1 \text{ V}$, $V_{OUT_LDOx} = 1 \text{ V}$, $V_{A} = 25 \text{ C}$, $V_{A} = 25$

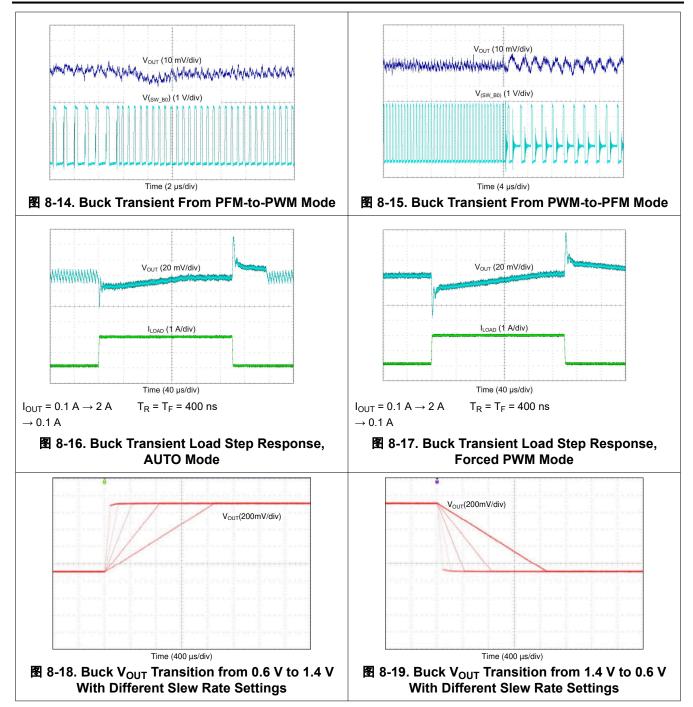


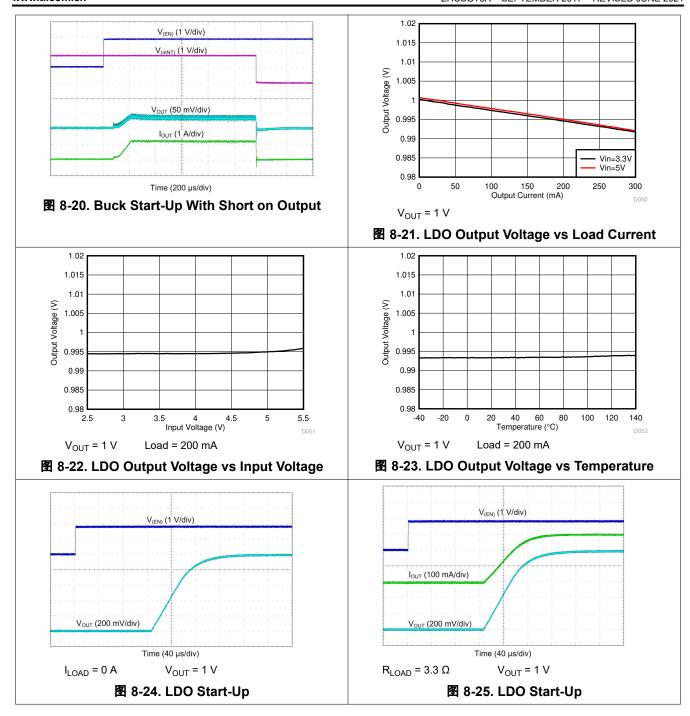
PFM/PWM Mode

PWM Mode

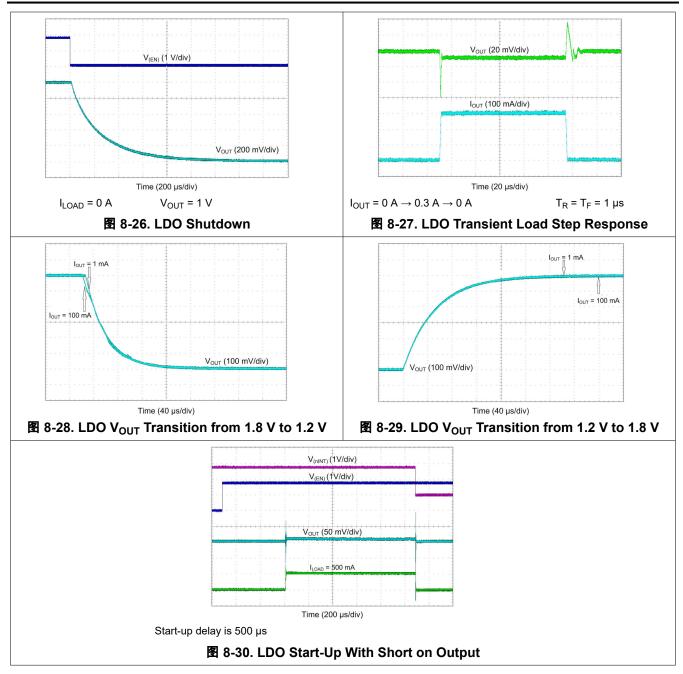












9 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 2.8 V and 5.5 V. The VANA input and VIN_Bx buck inputs must be connected together, and they must use the same input supply. This input supply must be well regulated and able to withstand maximum input current and maintain stable voltage without voltage drop even at load transition condition. The resistance of the input supply rail must be low enough that the input current transient does not cause too high a drop in the LP87332D-Q1 supply voltage that can cause false UVLO fault triggering. If the input supply is located more than a few inches from the LP87332D-Q1, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. The VIN_LDOx LDO input supply voltage range is 2.5 V to 5.5 V and can be higher or lower than VANA supply voltage.



10 Layout

10.1 Layout Guidelines

The high frequency and large switching currents of the LP87332D-Q1 make the choice of layout important. Good power supply results only occur when care is given to proper design and layout. Layout affects noise pickup and generation and can cause a good design to perform with less-than-expected results. With a range of output currents from milliamps to several amps, good power supply layout is much more difficult than most general PCB design. Use the following steps as a reference to ensure the device is stable and maintains proper voltage and current regulation across its intended operating voltage and current range.

- 1. Place C_{IN} as close as possible to the VIN_Bx pin and the PGND_Bx pin. Route the V_{IN} trace wide and thick to avoid IR drops. The trace between the positive node of the input capacitor and the VIN_Bx pins of LP87332D-Q1, as well as the trace between the negative node of the input capacitor and the power PGND_Bx pins, must be kept as short as possible. The input capacitance provides a low-impedance voltage source for the switching converter. The inductance of the connection is the most important parameter of a local decoupling capacitor parasitic inductance on these traces must be kept as small as possible for proper device operation. The parasitic inductance can be reduced by using a ground plane as close as possible to the top layer by using thin dielectric layer between the top layer and the ground plane.
- The output filter, consisting of L and COUT, converts the switching signal at SW_Bx to the noiseless output voltage. The output filter must be placed as close as possible to the device, keeping the switch node small for best EMI behavior. Route the traces between the output capacitors of the LP87332D-Q1 and the input capacitors of the load direct and wide to avoid losses due to the IR drop.
- Input for analog blocks (VANA and AGND) must be isolated from noisy signals. Connect VANA directly to a
 quiet system voltage node and AGND to a quiet ground point where no IR drop occurs. Place the decoupling
 capacitor as close as possible to the VANA pin.
- 4. If remote voltage sensing can be used for the load, connect the LP87332D-Q1 feedback pins FB_Bx to the respective sense pins on the load capacitor. The sense lines are susceptible to noise. They must be kept away from noisy signals such as PGND_Bx, VIN_Bx, and SW_Bx, as well as high bandwidth signals such as the I²C. Avoid both capacitive and inductive coupling by keeping the sense lines short and direct, and close to each other. Run the lines in a quiet layer. Isolate them from noisy signals by a voltage or ground plane if possible. If series resistors are used for load current measurement, place them after connection of the voltage feedback.
- 5. PGND_Bx, VIN_Bx and SW_Bx must be routed on thick layers. They must not surround inner signal layers which are not able to withstand interference from noisy PGND_Bx, VIN_Bx and SW_Bx.
- 6. LDO performance (PSRR, noise, and transient response) depend on the layout of the PCB. Best performance is achieved by placing CIN and COUT as close to the LP87332D-Q1 device as practical. The ground connections for CIN and COUT must be back to the LP87332D-Q1 AGND with as wide and as short of a copper trace as is practical and with multiple vias if routing is done on other layer. Avoid connections using long trace lengths, narrow trace widths, or connection through small via. These add parasitic inductances and resistance that results in inferior performance, especially during transient conditions.

Due to the small package of this converter and the overall small solution size, the thermal performance of the PCB layout is important. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power dissipation limits of a given component. Proper PCB layout, focusing on thermal performance, results in lower die temperatures. Wide power traces can sink dissipated heat. This can be improved further on multi-layer PCB designs with vias to different planes. This results in reduced junction-to-ambient ($R_{\theta JA}$) and junction-to-board ($R_{\theta JB}$) thermal resistances, thereby reducing the device junction temperature, T_J . TI strongly recommends performance of a careful system-level 2D or full 3D dynamic thermal analysis at the beginning product design process by using a thermal modeling analysis software.



10.2 Layout Example

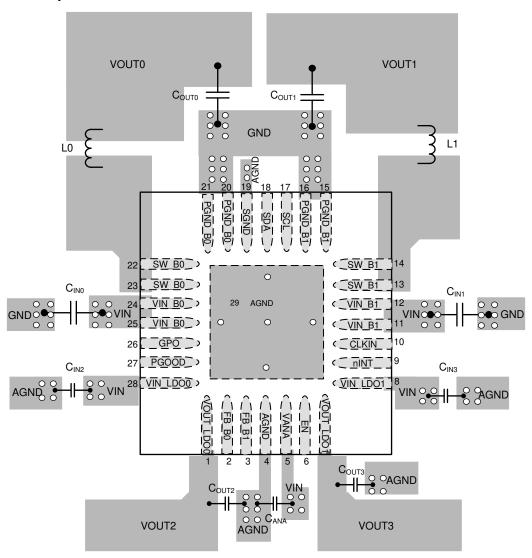


图 10-1. LP87332D-Q1 Board Layout

11 Device and Documentation Support

11.1 Device Support

11.1.1 第三方产品免责声明

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To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 支持资源

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11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary

TI Glossary This glo

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LP87332DRHDRQ1	ACTIVE	VQFN	RHD	28	3000	RoHS & Green		Level-2-260C-1 YEAR	-40 to 125	LP8733 2D-Q1	Samples
LP87332DRHDTQ1	ACTIVE	VQFN	RHD	28	250	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	LP8733 2D-Q1	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF LP87332D-Q1:

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 4-Jan-2023

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
I	LP87332DRHDRQ1	VQFN	RHD	28	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
	LP87332DRHDTQ1	VQFN	RHD	28	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2

PACKAGE MATERIALS INFORMATION

www.ti.com 4-Jan-2023



*All dimensions are nominal

Device	Package Type	Type Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)
LP87332DRHDRQ1	VQFN	RHD	28	3000	367.0	367.0	35.0
LP87332DRHDTQ1	VQFN	RHD	28	250	210.0	185.0	35.0

5 x 5 mm, 0.5 mm pitch

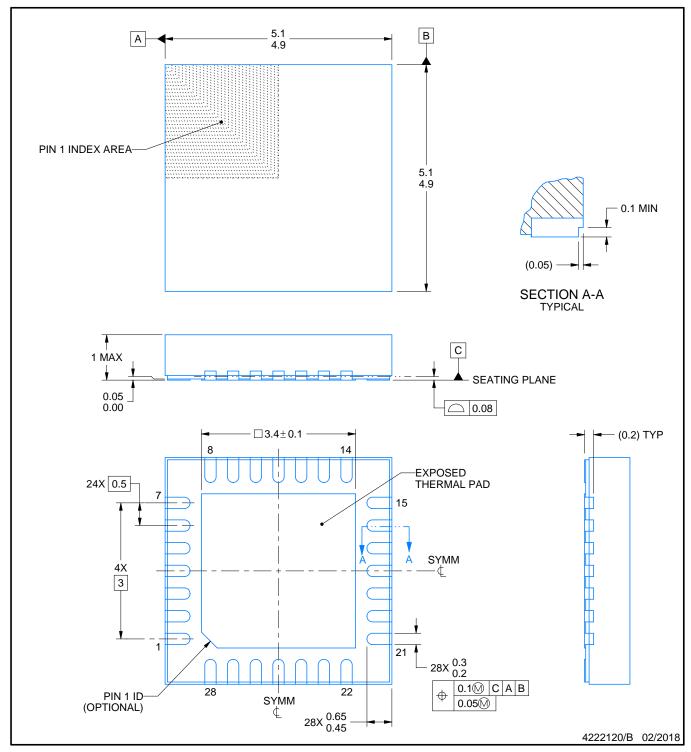
PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

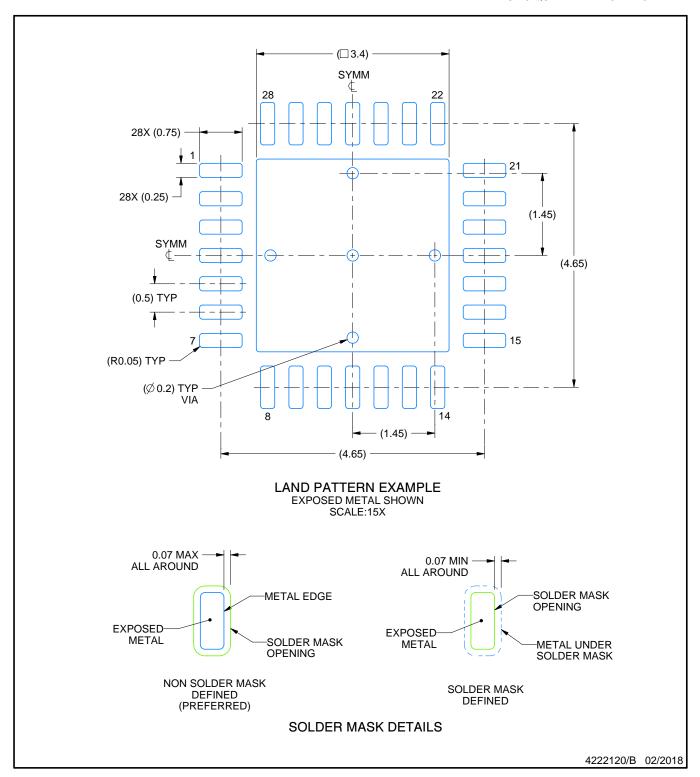
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

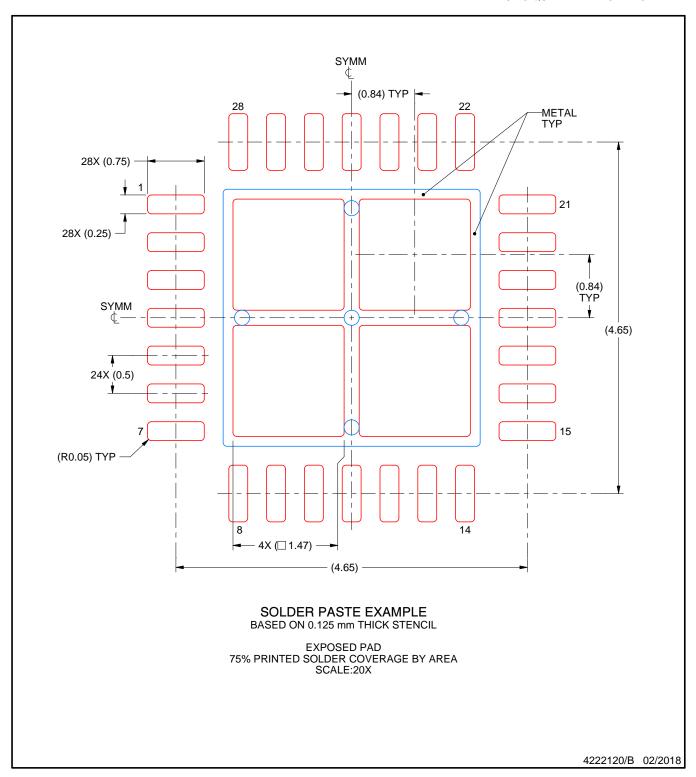


NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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